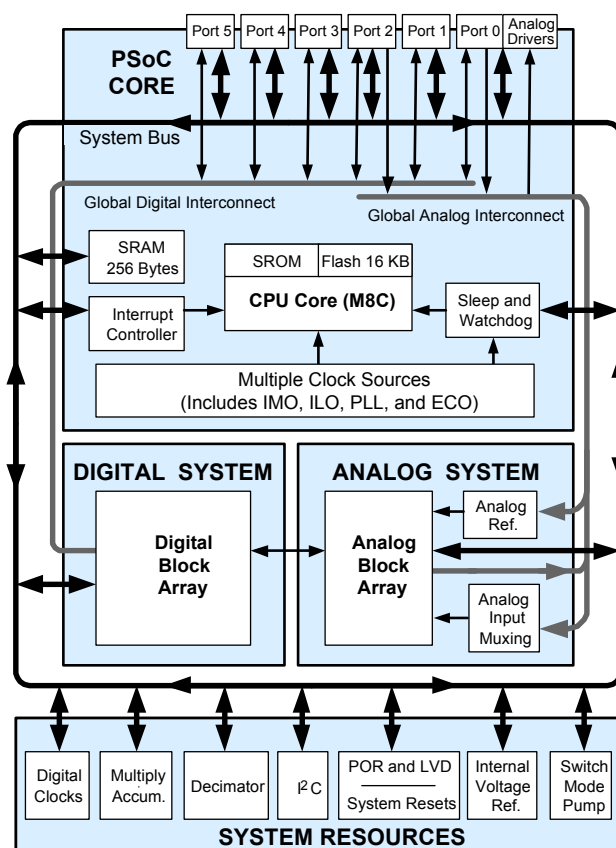


Features

- **Powerful Harvard-architecture processor**
 - M8C processor speeds up to 24 MHz
 - 8 × 8 multiply, 32-bit accumulate
 - Low power at high speed
 - Operating voltage: 3.0 V to 5.25 V
 - Operating voltages down to 1.0 V using on-chip switch mode pump (SMP)
 - Industrial temperature range: -40 °C to +85 °C
- **Advanced peripherals (PSoC[®] blocks)**
 - Twelve rail-to-rail analog PSoC blocks provide:
 - Up to 14-bit analog-to-digital converters (ADCs)
 - Up to 9-bit digital-to-analog converters (DACs)
 - Programmable gain amplifiers (PGAs)
 - Programmable filters and comparators
 - Eight digital PSoC blocks provide:
 - 8- to 32-bit timers and counters, 8- and 16-bit pulse-width modulators (PWMs)
 - Cyclical redundancy check (CRC) and pseudo random sequence (PRS) modules
 - Up to two full-duplex universal asynchronous receiver transmitters (UARTs)
 - Multiple serial peripheral interface (SPI) masters or slaves
 - Connectable to all general-purpose I/O (GPIO) pins
 - Complex peripherals by combining blocks
- **Precision, programmable clocking**
 - Internal 2.5% 24- / 48-MHz main oscillator
 - 24- / 48-MHz with optional 32 kHz crystal
 - Optional external oscillator up to 24 MHz
 - Internal oscillator for watchdog and sleep
- **Flexible on-chip memory**
 - 16 KB flash program storage 50,000 erase/write cycles
 - 256-bytes SRAM data storage
 - In-system serial programming (ISSP)
 - Partial flash updates
 - Flexible protection modes
 - Electronically erasable programmable read only memory (EEPROM) emulation in flash
- **Programmable pin configurations**
 - 25-mA sink, 10-mA source on all GPIOs
 - Pull-up, pull-down, high-Z, strong, or open-drain drive modes on all GPIOs
 - Eight standard analog inputs on GPIO, plus four additional analog inputs with restricted routing
 - Four 30-mA analog outputs on GPIOs
 - Configurable interrupt on all GPIOs

- **Additional system resources**
 - I²C slave, master, and multi-master to 400 kHz
 - Watchdog and sleep timers
 - User-configurable low-voltage detection (LVD)
 - Integrated supervisory circuit
 - On-chip precision voltage reference
- **Complete development tools**
 - Free development software (PSoC Designer™)
 - Full-featured, in-circuit emulator (ICE) and programmer
 - Full-speed emulation
 - Complex breakpoint structure
 - 128 KB trace memory

Logic Block Diagram



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PSoC Functional Overview

The PSoC family consists of many programmable system-on-chip controller devices. These devices are designed to replace multiple traditional microcontroller unit (MCU)-based system components with one, low-cost single-chip programmable device. PSoC devices include configurable blocks of analog and digital logic, as well as programmable interconnects. This architecture lets you to create customized peripheral configurations that match the requirements of each individual application. Additionally, a fast central processing unit (CPU), flash program memory, SRAM data memory, and configurable I/O are included in a range of convenient pinouts and packages.

The PSoC architecture, as illustrated in [Logic Block Diagram on page 1](#), consists of four main areas: PSoC core, digital system, analog system, and system resources. Configurable global busing allows all the device resources to be combined into a complete custom system. The PSoC CY8C27x43 family can have up to five I/O ports that connect to the global digital and analog interconnects, providing access to eight digital blocks and 12 analog blocks.

PSoC Core

The PSoC core is a powerful engine that supports a rich feature set. The core includes a CPU, memory, clocks, and configurable GPIO.

The M8C CPU core is a powerful processor with speeds up to 24 MHz, providing a four MIPS 8-bit Harvard architecture microprocessor. The CPU uses an interrupt controller with 17 vectors, to simplify programming of real time embedded events. Program execution is timed and protected using the included sleep and watchdog timers (WDT).

Memory encompasses 16 KB of flash for program storage, 256 bytes of SRAM for data storage, and up to 2 K of EEPROM emulated using the flash. Program flash uses four protection levels on blocks of 64 bytes, allowing customized software IP protection.

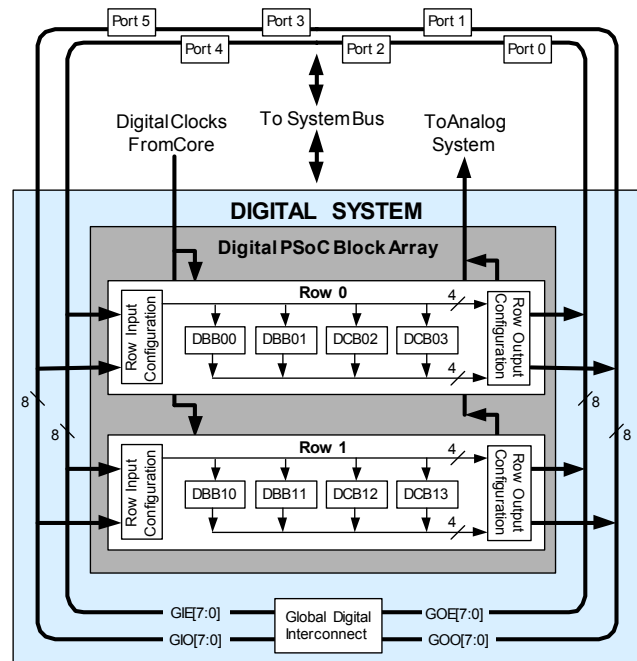
The PSoC device incorporates flexible internal clock generators, including a 24-MHz internal main oscillator (IMO) accurate to 2.5% over temperature and voltage. The 24-MHz IMO can also be doubled to 48 MHz for use by the digital system. A low power 32-kHz internal low speed oscillator (ILO) is provided for the sleep timer and WDT. If crystal accuracy is desired, the 32.768-kHz external crystal oscillator (ECO) is available for use as a Real Time Clock (RTC) and can optionally generate a crystal-accurate 24-MHz system clock using a PLL. The clocks, together with programmable clock dividers (as a system resource), provide the flexibility to integrate almost any timing requirement into the PSoC device.

PSoC GPIOs provide connection to the CPU, digital and analog resources of the device. Each pin's drive mode may be selected from eight options, allowing great flexibility in external interfacing. Every pin also has the capability to generate a system interrupt on high level, low level, and change from last read.

Digital System

The digital system is composed of eight digital PSoC blocks. Each block is an 8-bit resource that can be used alone or combined with other blocks to form 8-, 16-, 24-, and 32-bit peripherals, which are called user modules.

Figure 1. Digital System Block Diagram



Digital peripheral configurations include:

- PWMs (8- and 16-bit)
- PWMs with dead band (8- and 16-bit)
- Counters (8- to 32-bit)
- Timers (8- to 32-bit)
- UART 8-bit with selectable parity (up to two)
- SPI slave and master (up to two)
- I²C slave and multi-master (one available as a system resource)
- CRC/generator (8- to 32-bit)
- IrDA (up to two)
- Pseudo random sequence (PRS) generators (8- to 32-bit)

The digital blocks can be connected to any GPIO through a series of global buses that can route any signal to any pin. The buses also enable signal multiplexing and for performing logic operations. This configurability frees your designs from the constraints of a fixed peripheral controller.

Digital blocks are provided in rows of four, where the number of blocks varies by PSoC device family. This lets you the optimum choice of system resources for your application. Family resources are shown in the table titled [PSoC Device Characteristics on page 5](#).

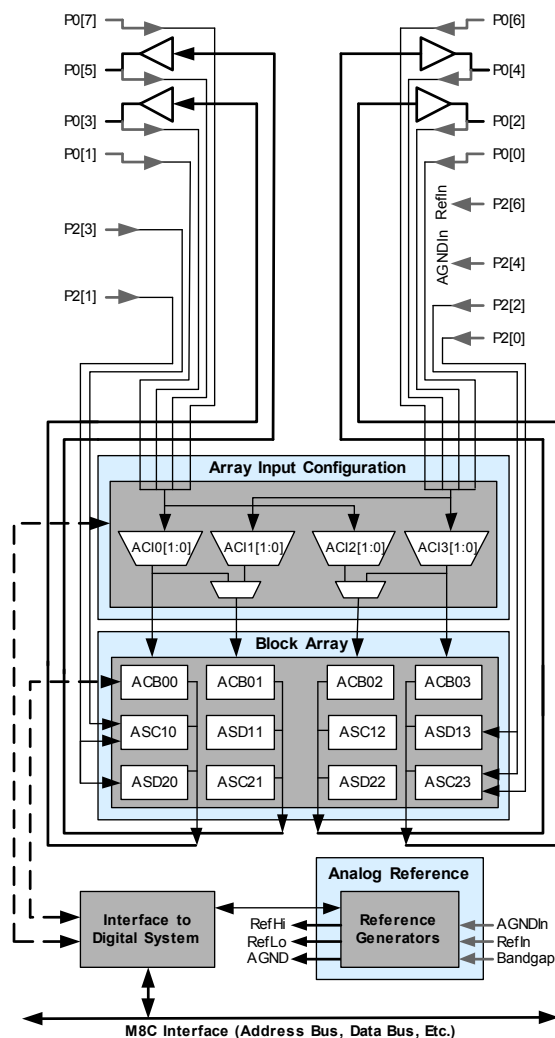
Analog System

The analog system is composed of 12 configurable blocks, each comprised of an opamp circuit allowing the creation of complex analog signal flows. Analog peripherals are very flexible and can be customized to support specific application requirements. Some of the more common PSoC analog functions (most available as user modules) are as follows:

- ADCs (up to 4, with 6- to 14-bit resolution, selectable as incremental, delta sigma, and SAR)
- Filters (2, 4, 6, and 8 pole band pass, low pass, and notch)
- Amplifiers (up to four, with selectable gain to 48x)
- Instrumentation amplifiers (up to two, with selectable gain to 93x)
- Comparators (up to four, with 16 selectable thresholds)
- DACs (up to four, with 6- to 9-bit resolution)
- Multiplying DACs (up to four, with 6- to 9-bit resolution)
- High current output drivers (four with 30 mA drive as a core resource)
- 1.3-V reference (as a system resource)
- DTMF dialer
- Modulators
- Correlators
- Peak detectors
- Many other topologies possible

Analog blocks are provided in columns of three, which includes one continuous time (CT) and two switched capacitor (SC) blocks, as shown in the following figure.

Figure 2. Analog System Block Diagram



Additional System Resources

System resources, some of which have been previously listed, provide additional capability useful to complete systems. Additional resources include a multiplier, decimator, switch mode pump, low voltage detection, and power on reset.

- Digital clock dividers provide three customizable clock frequencies for use in applications. The clocks can be routed to both the digital and analog systems. Additional clocks can be generated using digital PSoC blocks as clock dividers.
- Multiply accumulate (MAC) provides fast 8-bit multiplier with 32-bit accumulate, to assist in general math and digital filters.
- The decimator provides a custom hardware filter for digital signal processing applications including the creation of Delta Sigma ADCs.

- The I²C module provides 100 and 400 kHz communication over two wires. Slave, master, and multi-master modes are all supported.
- LVD interrupts can signal the application of falling voltage levels, while the advanced power-on reset (POR) circuit eliminates the need for a system supervisor.
- An internal 1.3-V reference provides an absolute reference for the analog system, including ADCs and DACs.
- An integrated switch mode pump (SMP) generates normal operating voltages from a single 1.2-V battery cell, providing a low cost boost converter.

PSoC Device Characteristics

Depending on your PSoC device characteristics, the digital and analog systems can have 16, 8, or 4 digital blocks and 12, 6, or 4 analog blocks. The following table lists the resources available for specific PSoC device groups. The PSoC device covered by this datasheet is highlighted in [Table 1](#).

Table 1. PSoC Device Characteristics

| PSoC Part Number | Digital I/O | Digital Rows | Digital Blocks | Analog Inputs | Analog Outputs | Analog Columns | Analog Blocks | SRAM Size | Flash Size |
|------------------|-------------|--------------|----------------|---------------|----------------|----------------|-----------------------------|-----------|------------|
| CY8C29x66 | up to 64 | 4 | 16 | up to 12 | 4 | 4 | 12 | 2 K | 32 K |
| CY8C28xxx | up to 44 | up to 3 | up to 12 | up to 44 | up to 4 | up to 6 | up to 12 + 4 ^[1] | 1 K | 16 K |
| CY8C27x43 | up to 44 | 2 | 8 | up to 12 | 4 | 4 | 12 | 256 | 16 K |
| CY8C24x94 | up to 56 | 1 | 4 | up to 48 | 2 | 2 | 6 | 1 K | 16 K |
| CY8C24x23A | up to 24 | 1 | 4 | up to 12 | 2 | 2 | 6 | 256 | 4 K |
| CY8C23x33 | up to 26 | 1 | 4 | up to 12 | 2 | 2 | 4 | 256 | 8 K |
| CY8C22x45 | up to 38 | 2 | 8 | up to 38 | 0 | 4 | 6 ^[1] | 1 K | 16 K |
| CY8C21x45 | up to 24 | 1 | 4 | up to 24 | 0 | 4 | 6 ^[1] | 512 | 8 K |
| CY8C21x34 | up to 28 | 1 | 4 | up to 28 | 0 | 2 | 4 ^[1] | 512 | 8 K |
| CY8C21x23 | up to 16 | 1 | 4 | up to 8 | 0 | 2 | 4 ^[1] | 256 | 4 K |
| CY8C20x34 | up to 28 | 0 | 0 | up to 28 | 0 | 0 | 3 ^[1, 2] | 512 | 8 K |
| CY8C20xx6 | up to 36 | 0 | 0 | up to 36 | 0 | 0 | 3 ^[1, 2] | up to 2 K | up to 32 K |

Notes

1. Limited analog functionality.
2. Two analog blocks and one CapSense®.

Getting Started

For in depth information, along with detailed programming details, see the PSoC® [Technical Reference Manual](#).

For up-to-date ordering, packaging, and electrical specification information, see the latest [PSoC device datasheets](#) on the web.

Application Notes

[Cypress application notes](#) are an excellent introduction to the wide variety of possible PSoC designs.

Development Kits

[PSoC Development Kits](#) are available online from and through a growing number of regional and global distributors, which include Arrow, Avnet, Digi-Key, Farnell, Future Electronics, and Newark.

Training

[Free PSoC technical training](#) (on demand, webinars, and workshops), which is available online via www.cypress.com, covers a wide variety of topics and skill levels to assist you in your designs.

CYPros Consultants

Certified PSoC Consultants offer everything from technical assistance to completed PSoC designs. To contact or become a PSoC Consultant go to the [CYPros Consultants](#) web site.

Solutions Library

Visit our growing [library of solution focused designs](#). Here you can find various application designs that include firmware and hardware design files that enable you to complete your designs quickly.

Technical Support

[Technical support](#) – including a searchable Knowledge Base articles and technical forums – is also available online. If you cannot find an answer to your question, call our Technical Support hotline at 1-800-541-4736.

Development Tools

PSoC Designer™ is the revolutionary Integrated Design Environment (IDE) that you can use to customize PSoC to meet your specific application requirements. PSoC Designer software accelerates system design and time to market. Develop your applications using a library of precharacterized analog and digital peripherals (called user modules) in a drag-and-drop design environment. Then, customize your design by leveraging the dynamically generated application programming interface (API) libraries of code. Finally, debug and test your designs with the integrated debug environment, including in-circuit emulation and standard software debug features. PSoC Designer includes:

- Application editor graphical user interface (GUI) for device and user module configuration and dynamic reconfiguration
- Extensive user module catalog
- Integrated source-code editor (C and assembly)
- Free C compiler with no size restrictions or time limits
- Built-in debugger
- In-circuit emulation
- Built-in support for communication interfaces:
 - Hardware and software I²C slaves and masters
 - Full-speed USB 2.0
 - Up to four full-duplex universal asynchronous receiver/transmitters (UARTs), SPI master and slave, and wireless

PSoC Designer supports the entire library of PSoC 1 devices and runs on Windows XP, Windows Vista, and Windows 7.

PSoC Designer Software Subsystems

Design Entry

In the chip-level view, choose a base device to work with. Then select different onboard analog and digital components that use the PSoC blocks, which are called user modules. Examples of user modules are analog-to-digital converters (ADCs), digital-to-analog converters (DACs), amplifiers, and filters. Configure the user modules for your chosen application and connect them to each other and to the proper pins. Then generate your project. This prepopulates your project with APIs and libraries that you can use to program your application.

The tool also supports easy development of multiple configurations and dynamic reconfiguration. Dynamic reconfiguration makes it possible to change configurations at run time. In essence, this lets you to use more than 100 percent of PSoC's resources for an application.

Code Generation Tools

The code generation tools work seamlessly within the PSoC Designer interface and have been tested with a full range of debugging tools. You can develop your design in C, assembly, or a combination of the two.

Assemblers. The assemblers allow you to merge assembly code seamlessly with C code. Link libraries automatically use absolute addressing or are compiled in relative mode, and linked with other software modules to get absolute addressing.

C Language Compilers. C language compilers are available that support the PSoC family of devices. The products allow you to create complete C programs for the PSoC family devices. The optimizing C compilers provide all of the features of C, tailored to the PSoC architecture. They come complete with embedded libraries providing port and bus operations, standard keypad and display support, and extended math functionality.

Debugger

PSoC Designer has a debug environment that provides hardware in-circuit emulation, allowing you to test the program in a physical system while providing an internal view of the PSoC device. Debugger commands allow you to read and program and read and write data memory, and read and write I/O registers. You can read and write CPU registers, set and clear breakpoints, and provide program run, halt, and step control. The debugger also lets you to create a trace buffer of registers and memory locations of interest.

Online Help System

The online help system displays online, context-sensitive help. Designed for procedural and quick reference, each functional subsystem has its own context-sensitive help. This system also provides tutorials and links to FAQs and an Online Support Forum to aid the designer.

In-Circuit Emulator

A low-cost, high-functionality In-Circuit Emulator (ICE) is available for development support. This hardware can program single devices.

The emulator consists of a base unit that connects to the PC using a USB port. The base unit is universal and operates with all PSoC devices. Emulation pods for each device family are available separately. The emulation pod takes the place of the PSoC device in the target board and performs full-speed (24-MHz) operation.

Designing with PSoC Designer

The development process for the PSoC device differs from that of a traditional fixed function microprocessor. The configurable analog and digital hardware blocks give the PSoC architecture a unique flexibility that pays dividends in managing specification change during development and by lowering inventory costs. These configurable resources, called PSoC Blocks, have the ability to implement a wide variety of user-selectable functions. The PSoC development process is summarized in four steps:

1. Select [User Modules](#).
2. Configure user modules.
3. Organize and connect.
4. Generate, verify, and debug.

Select User Modules

PSoC Designer provides a library of prebuilt, pretested hardware peripheral components called “user modules.” User modules make selecting and implementing peripheral devices, both analog and digital, simple.

Configure User Modules

Each user module that you select establishes the basic register settings that implement the selected function. They also provide parameters and properties that allow you to tailor their precise configuration to your particular application. For example, a pulse width modulator (PWM) User Module configures one or more digital PSoC blocks, one for each 8 bits of resolution. The user module parameters permit you to establish the pulse width and duty cycle. Configure the parameters and properties to correspond to your chosen application. Enter values directly or by selecting values from drop-down menus. All the user modules are documented in datasheets that may be viewed directly in PSoC Designer or on the Cypress website. These [user module datasheets](#) explain the internal operation of the user module and provide performance specifications. Each datasheet describes the use of each user module parameter, and other information you may need to successfully implement your design.

Organize and Connect

You build signal chains at the chip level by interconnecting user modules to each other and the I/O pins. You perform the selection, configuration, and routing so that you have complete control over all on-chip resources.

Generate, Verify, and Debug

When you are ready to test the hardware configuration or move on to developing code for the project, you perform the “Generate Configuration Files” step. This causes PSoC Designer to generate source code that automatically configures the device to your specification and provides the software for the system. The generated code provides application programming interfaces (APIs) with high-level functions to control and respond to hardware events at run time and interrupt service routines that you can adapt as needed.

A complete code development environment lets you to develop and customize your applications in either C, assembly language, or both.

The last step in the development process takes place inside PSoC Designer’s debugger (access by clicking the Connect icon). PSoC Designer downloads the HEX image to the ICE where it runs at full speed. PSoC Designer debugging capabilities rival those of systems costing many times more. In addition to traditional single-step, run-to-breakpoint and watch-variable features, the debug interface provides a large trace buffer and lets you to define complex breakpoint events that include monitoring address and data bus values, memory locations and external signals.

Pinouts

The CY8C27x43 PSoC device is available in a variety of packages which are listed and illustrated in the following tables. Every port pin (labeled with a "P") is capable of Digital I/O. However, V_{SS}, V_{DD}, SMP, and XRES are not capable of Digital I/O.

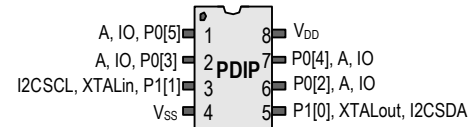
8-pin Part Pinout

Table 2. Pin Definitions – 8-pin PDIP

| Pin No. | Type | | Pin Name | Description |
|---------|---------|--------|-----------------|---|
| | Digital | Analog | | |
| 1 | I/O | I/O | P0[5] | Analog column mux input and column output |
| 2 | I/O | I/O | P0[3] | Analog column mux input and column output |
| 3 | I/O | | P1[1] | Crystal Input (XTALin), I ² C serial clock (SCL), ISSP-SCLK ³ |
| 4 | Power | | V _{SS} | Ground connection. |
| 5 | I/O | | P1[0] | Crystal output (XTALout), I ² C serial data (SDA), ISSP-SDATA ³ |
| 6 | I/O | I/O | P0[2] | Analog column mux input and column output |
| 7 | I/O | I/O | P0[4] | Analog column mux input and column output |
| 8 | Power | | V _{DD} | Supply voltage |

LEGEND: A = Analog, I = Input, and O = Output.

Figure 3. CY8C27143 8-pin PSoC Device



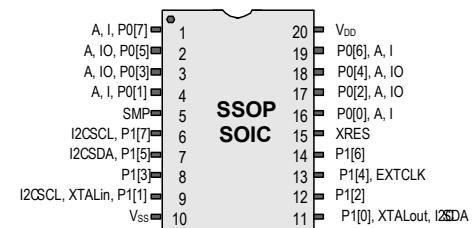
20-pin Part Pinout

Table 3. Pin Definitions – 20-pin SSOP, SOIC

| Pin No. | Type | | Pin Name | Description |
|---------|---------|--------|-----------------|---|
| | Digital | Analog | | |
| 1 | I/O | I | P0[7] | Analog column mux input |
| 2 | I/O | I/O | P0[5] | Analog column mux input and column output |
| 3 | I/O | I/O | P0[3] | Analog column mux input and column output |
| 4 | I/O | I | P0[1] | Analog column mux input |
| 5 | Power | | SMP | Switch Mode Pump (SMP) connection to external components required |
| 6 | I/O | | P1[7] | I ² C Serial Clock (SCL) |
| 7 | I/O | | P1[5] | I ² C Serial Data (SDA) |
| 8 | I/O | | P1[3] | |
| 9 | I/O | | P1[1] | Crystal input (XTALin), I ² C SCL, ISSP-SCLK ³ |
| 10 | Power | | V _{SS} | Ground connection. |
| 11 | I/O | | P1[0] | Crystal output (XTALout), I ² C SDA, ISSP-SDATA ³ |
| 12 | I/O | | P1[2] | |
| 13 | I/O | | P1[4] | Optional external clock input (EXTCLK) |
| 14 | I/O | | P1[6] | |
| 15 | Input | | XRES | Active high external reset with internal pull down |
| 16 | I/O | I | P0[0] | Analog column mux input |
| 17 | I/O | I/O | P0[2] | Analog column mux input and column output |
| 18 | I/O | I/O | P0[4] | Analog column mux input and column output |
| 19 | I/O | I | P0[6] | Analog column mux input |
| 20 | Power | | V _{DD} | Supply voltage |

LEGEND: A = Analog, I = Input, and O = Output.

Figure 4. CY8C27243 20-pin PSoC Device



Note

- These are the ISSP pins, which are not High Z at POR (Power On Reset). See the *PSoC Programmable System-on-Chip Technical Reference Manual* for details.

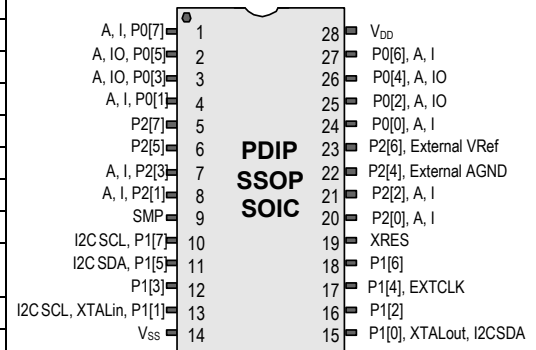
28-pin Part Pinout

Table 4. Pin Definitions – 28-pin PDIP, SSOP, SOIC

| Pin No. | Type | | Pin Name | Description |
|---------|---------|--------|-----------------|---|
| | Digital | Analog | | |
| 1 | I/O | I | P0[7] | Analog column mux input |
| 2 | I/O | I/O | P0[5] | Analog column mux input and column output |
| 3 | I/O | I/O | P0[3] | Analog column mux input and column output |
| 4 | I/O | I | P0[1] | Analog column mux input |
| 5 | I/O | | P2[7] | |
| 6 | I/O | | P2[5] | |
| 7 | I/O | I | P2[3] | Direct switched capacitor block input |
| 8 | I/O | I | P2[1] | Direct switched capacitor block input |
| 9 | Power | | SMP | Switch mode pump (SMP) connection to external components required |
| 10 | I/O | | P1[7] | I ² C SCL |
| 11 | I/O | | P1[5] | I ² C SDA |
| 12 | I/O | | P1[3] | |
| 13 | I/O | | P1[1] | Crystal input (XTALin), I ² C SCL, ISSP-SCLK ^[4] |
| 14 | Power | | Vss | Ground connection. |
| 15 | I/O | | P1[0] | Crystal output (XTALout), I ² C SDA, ISSP-SDATA ^[4] |
| 16 | I/O | | P1[2] | |
| 17 | I/O | | P1[4] | Optional external clock input (EXTCLK) |
| 18 | I/O | | P1[6] | |
| 19 | Input | | XRES | Active high external reset with internal pull down |
| 20 | I/O | I | P2[0] | Direct switched capacitor block input |
| 21 | I/O | I | P2[2] | Direct switched capacitor block input |
| 22 | I/O | | P2[4] | External analog ground (AGND) |
| 23 | I/O | | P2[6] | External voltage reference (V _{REF}) |
| 24 | I/O | I | P0[0] | Analog column mux input |
| 25 | I/O | I/O | P0[2] | Analog column mux input and column output |
| 26 | I/O | I/O | P0[4] | Analog column mux input and column output |
| 27 | I/O | I | P0[6] | Analog column mux input |
| 28 | Power | | V _{DD} | Supply voltage |

LEGEND: A = Analog, I = Input, and O = Output.

Figure 5. CY8C27443 28-pin PSoC Device



Note

4. These are the ISSP pins, which are not High Z at POR (Power On Reset). See the *PSoC Programmable System-on-Chip Technical Reference Manual* for details.

48-pin Part Pinout

Table 6. Pin Definitions – 48-pin Part Pinout (SSOP)

| Pin No. | Type | | Pin Name | Description |
|---------|---------|--------|-----------------|---|
| | Digital | Analog | | |
| 1 | I/O | I | P0[7] | Analog column mux input |
| 2 | I/O | I/O | P0[5] | Analog column mux input and column output |
| 3 | I/O | I/O | P0[3] | Analog column mux input and column output |
| 4 | I/O | I | P0[1] | Analog column mux input |
| 5 | I/O | | P2[7] | |
| 6 | I/O | | P2[5] | |
| 7 | I/O | I | P2[3] | Direct switched capacitor block input |
| 8 | I/O | I | P2[1] | Direct switched capacitor block input |
| 9 | I/O | | P4[7] | |
| 10 | I/O | | P4[5] | |
| 11 | I/O | | P4[3] | |
| 12 | I/O | | P4[1] | |
| 13 | Power | | SMP | SMP connection to external components required |
| 14 | I/O | | P3[7] | |
| 15 | I/O | | P3[5] | |
| 16 | I/O | | P3[3] | |
| 17 | I/O | | P3[1] | |
| 18 | I/O | | P5[3] | |
| 19 | I/O | | P5[1] | |
| 20 | I/O | | P1[7] | I ² C SCL |
| 21 | I/O | | P1[5] | I ² C SDA |
| 22 | I/O | | P1[3] | |
| 23 | I/O | | P1[1] | Crystal Input (XTALin), I ² C SCL, ISSP-SCLK ^[6] |
| 24 | Power | | Vss | Ground connection |
| 25 | I/O | | P1[0] | Crystal output (XTALout), I ² C SDA, ISSP-SDATA ^[6] |
| 26 | I/O | | P1[2] | |
| 27 | I/O | | P1[4] | Optional external clock input (EXTCLK) |
| 28 | I/O | | P1[6] | |
| 29 | I/O | | P5[0] | |
| 30 | I/O | | P5[2] | |
| 31 | I/O | | P3[0] | |
| 32 | I/O | | P3[2] | |
| 33 | I/O | | P3[4] | |
| 34 | I/O | | P3[6] | |
| 35 | Input | | XRES | Active high external reset with internal pull down |
| 36 | I/O | | P4[0] | |
| 37 | I/O | | P4[2] | |
| 38 | I/O | | P4[4] | |
| 39 | I/O | | P4[6] | |
| 40 | I/O | I | P2[0] | Direct switched capacitor block input |
| 41 | I/O | I | P2[2] | Direct switched capacitor block input |
| 42 | I/O | | P2[4] | External analog ground (AGND) |
| 43 | I/O | | P2[6] | External voltage reference (VRef) |
| 44 | I/O | I | P0[0] | Analog column mux input |
| 45 | I/O | I/O | P0[2] | Analog column mux input and column output |
| 46 | I/O | I/O | P0[4] | Analog column mux input and column output |
| 47 | I/O | I | P0[6] | Analog column mux input |
| 48 | Power | | V _{DD} | Supply voltage |

LEGEND: A = Analog, I = Input, and O = Output.

Note

6. These are the ISSP pins, which are not High Z at POR (Power On Reset). See the *PSoC Programmable System-on-Chip Technical Reference Manual* for details.

Figure 7. CY8C27643 48-pin PSoC Device

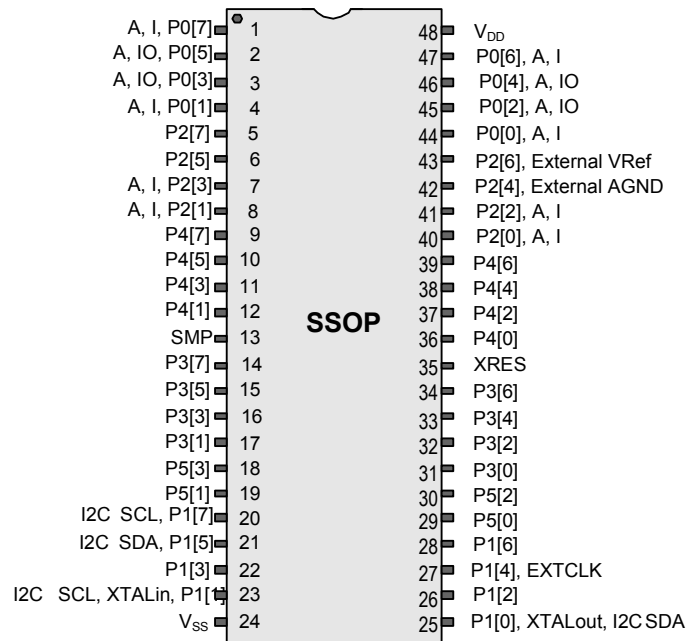


Table 7. Pin Definitions – 48-pin Part Pinout (QFN)

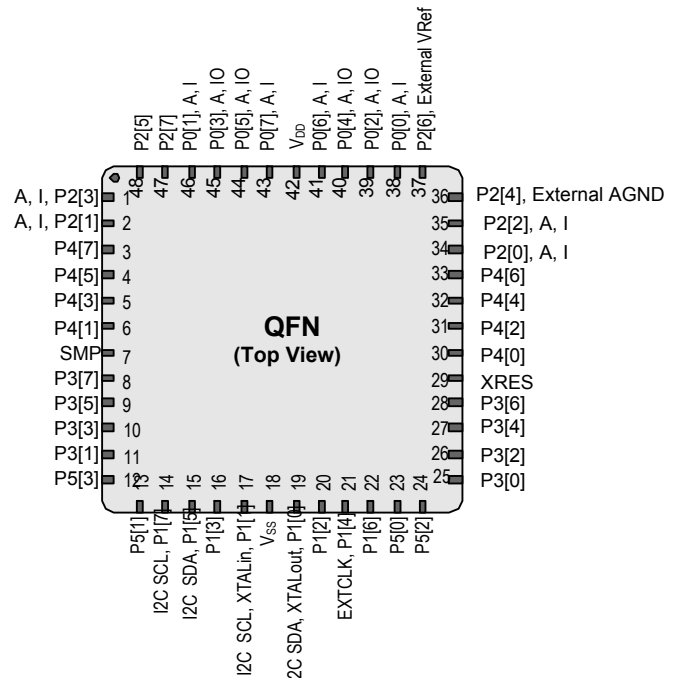
| Pin No. | Type | | Pin Name | Description |
|---------|---------|--------|-----------------|---|
| | Digital | Analog | | |
| 1 | I/O | I | P2[3] | Direct switched capacitor block input |
| 2 | I/O | I | P2[1] | Direct switched capacitor block input |
| 3 | I/O | | P4[7] | |
| 4 | I/O | | P4[5] | |
| 5 | I/O | | P4[3] | |
| 6 | I/O | | P4[1] | |
| 7 | Power | | SMP | SMP connection to external components required |
| 8 | I/O | | P3[7] | |
| 9 | I/O | | P3[5] | |
| 10 | I/O | | P3[3] | |
| 11 | I/O | | P3[1] | |
| 12 | I/O | | P5[3] | |
| 13 | I/O | | P5[1] | |
| 14 | I/O | | P1[7] | I ² C SCL |
| 15 | I/O | | P1[5] | I ² C SDA |
| 16 | I/O | | P1[3] | |
| 17 | I/O | | P1[1] | Crystal input (XTALin), I ² C SCL, ISSP-SCLK ^[8] |
| 18 | Power | | Vss | Ground connection. |
| 19 | I/O | | P1[0] | Crystal output (XTALout), I ² C SDA, ISSP-SDATA ^[8] |
| 20 | I/O | | P1[2] | |
| 21 | I/O | | P1[4] | Optional external clock input (EXTCLK) |
| 22 | I/O | | P1[6] | |
| 23 | I/O | | P5[0] | |
| 24 | I/O | | P5[2] | |
| 25 | I/O | | P3[0] | |
| 26 | I/O | | P3[2] | |
| 27 | I/O | | P3[4] | |
| 28 | I/O | | P3[6] | |
| 29 | Input | | XRES | Active high external reset with internal pull down |
| 30 | I/O | | P4[0] | |
| 31 | I/O | | P4[2] | |
| 32 | I/O | | P4[4] | |
| 33 | I/O | | P4[6] | |
| 34 | I/O | I | P2[0] | Direct switched capacitor block input |
| 35 | I/O | I | P2[2] | Direct switched capacitor block input |
| 36 | I/O | | P2[4] | External analog ground (AGND) |
| 37 | I/O | | P2[6] | External voltage reference (V _{REF}) |
| 38 | I/O | I | P0[0] | Analog column mux input |
| 39 | I/O | I/O | P0[2] | Analog column mux input and column output |
| 40 | I/O | I/O | P0[4] | Analog column mux input and column output |
| 41 | I/O | I | P0[6] | Analog column mux input |
| 42 | Power | | V _{DD} | Supply voltage |
| 43 | I/O | I | P0[7] | Analog column mux input |
| 44 | I/O | I/O | P0[5] | Analog column mux input and column output |
| 45 | I/O | I/O | P0[3] | Analog column mux input and column output |
| 46 | I/O | I | P0[1] | Analog column mux input |
| 47 | I/O | | P2[7] | |
| 48 | I/O | | P2[5] | |

LEGEND: A = Analog, I = Input, and O = Output.

Notes

- The QFN package has a center pad that must be connected to ground (Vss).
- These are the ISSP pins, which are not High Z at POR (Power On Reset). See the [PSoC Technical Reference Manual](#) for details.

Figure 8. CY8C27643 48-pin PSoC Device^[7]



56-pin Part Pinout

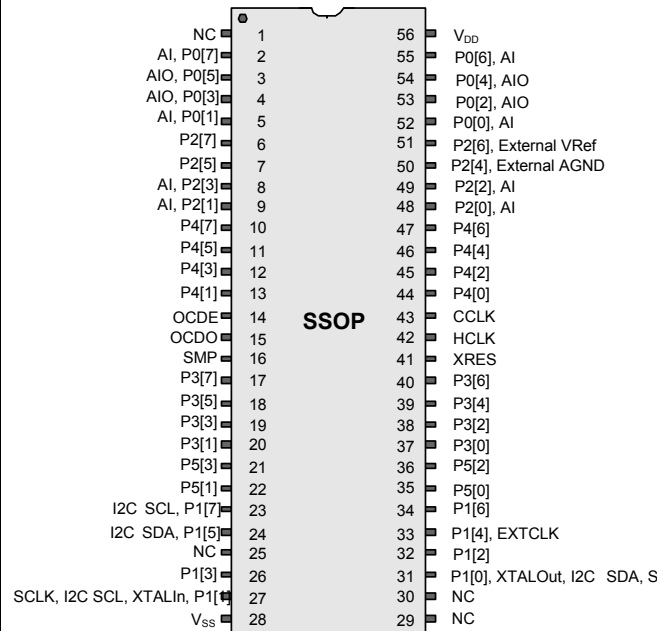
The 56-pin SSOP part is for the CY8C27002 On-Chip Debug (OCD) PSoC device.

Note This part is only used for in-circuit debugging. It is NOT available for production.

Table 8. Pin Definitions – 56-pin Part Pinout (SSOP)

| Pin No. | Type | | Pin Name | Description |
|---------|---------|--------|-----------------|---|
| | Digital | Analog | | |
| 1 | | | NC | No connection. Pin must be left floating |
| 2 | I/O | I | P0[7] | Analog column mux input |
| 3 | I/O | I | P0[5] | Analog column mux input and column output |
| 4 | I/O | I | P0[3] | Analog column mux input and column output |
| 5 | I/O | I | P0[1] | Analog column mux input |
| 6 | I/O | | P2[7] | |
| 7 | I/O | | P2[5] | |
| 8 | I/O | I | P2[3] | Direct switched capacitor block input |
| 9 | I/O | I | P2[1] | Direct switched capacitor block input |
| 10 | I/O | | P4[7] | |
| 11 | I/O | | P4[5] | |
| 12 | I/O | I | P4[3] | |
| 13 | I/O | I | P4[1] | |
| 14 | OCD | | OCDE | OCD even data I/O |
| 15 | OCD | | OCDO | OCD odd data output |
| 16 | Power | | SMP | SMP connection to required external components |
| 17 | I/O | | P3[7] | |
| 18 | I/O | | P3[5] | |
| 19 | I/O | | P3[3] | |
| 20 | I/O | | P3[1] | |
| 21 | I/O | | P5[3] | |
| 22 | I/O | | P5[1] | |
| 23 | I/O | | P1[7] | I ² C SCL |
| 24 | I/O | | P1[5] | I ² C SDA |
| 25 | | | NC | No connection. Pin must be left floating |
| 26 | I/O | | P1[3] | |
| 27 | I/O | | P1[1] | Crystal Input (XTALin), I ² C SCL, ISSP-SCLK ^[9] |
| 28 | Power | | V _{DD} | Supply voltage |
| 29 | | | NC | No connection. Pin must be left floating |
| 30 | | | NC | No connection. Pin must be left floating |
| 31 | I/O | | P1[0] | Crystal output (XTALout), I ² C SDA, ISSP-SDATA ^[9] |
| 32 | I/O | | P1[2] | |
| 33 | I/O | | P1[4] | Optional external clock input (EXTCLK) |
| 34 | I/O | | P1[6] | |
| 35 | I/O | | P5[0] | |
| 36 | I/O | | P5[2] | |
| 37 | I/O | | P3[0] | |
| 38 | I/O | | P3[2] | |
| 39 | I/O | | P3[4] | |
| 40 | I/O | | P3[6] | |

Figure 9. CY8C27002 56-pin PSoC Device



Not for Production

Note

9. These are the ISSP pins, which are not High Z at POR (Power On Reset). See the *PSoC Programmable System-on-Chip Technical Reference Manual* for details.

Table 8. Pin Definitions – 56-pin Part Pinout (SSOP) (continued)

| Pin No. | Type | | Pin Name | Description |
|---------|---------|--------|-----------------|---|
| | Digital | Analog | | |
| 42 | OCD | | HCLK | OCD high-speed clock output |
| 43 | OCD | | CCLK | OCD CPU clock output |
| 44 | I/O | | P4[0] | |
| 45 | I/O | | P4[2] | |
| 46 | I/O | | P4[4] | |
| 47 | I/O | | P4[6] | |
| 48 | I/O | I | P2[0] | Direct switched capacitor block input |
| 49 | I/O | I | P2[2] | Direct switched capacitor block input |
| 50 | I/O | | P2[4] | External Analog Ground (AGND) |
| 51 | I/O | | P2[6] | External Voltage Reference (VRef) |
| 52 | I/O | I | P0[0] | Analog column mux input |
| 53 | I/O | I | P0[2] | Analog column mux input and column output |
| 54 | I/O | I | P0[4] | Analog column mux input and column output |
| 55 | I/O | I | P0[6] | Analog column mux input |
| 56 | Power | | V _{DD} | Supply voltage |

LEGEND: A = Analog, I = Input, O = Output, and OCD = On-Chip Debug.

Register Reference

This section lists the registers of the CY8C27x43 PSoC device. For detailed register information, see the [PSoC Programmable System-on-Chip Technical Reference Manual](#).

Register Conventions

The register conventions specific to this section are listed in the following table.

Table 9. Register Conventions

| Convention | Description |
|------------|------------------------------|
| R | Read register or bit(s) |
| W | Write register or bit(s) |
| L | Logical register or bit(s) |
| C | Clearable register or bit(s) |
| # | Access is bit specific |

Register Mapping Tables

The PSoC device has a total register address space of 512 bytes. The register space is referred to as I/O space and is divided into two banks. The XO1 bit in the Flag register (CPU_F) determines which bank the user is currently in. When the XO1 bit is set, the user is in Bank 1.

Note In the following register mapping tables, blank fields are reserved and must not be accessed.

Table 10. Register Map Bank 0 Table: User Space

| Name | Addr (0.Hex) | Access | Name | Addr (0.Hex) | Access | Name | Addr (0.Hex) | Access | Name | Addr (0.Hex) | Access |
|----------|--------------|--------|---------|--------------|--------|----------|--------------|--------|----------|--------------|--------|
| PRT0DR | 00 | RW | | 40 | | ASC10CR0 | 80 | RW | | C0 | |
| PRT0IE | 01 | RW | | 41 | | ASC10CR1 | 81 | RW | | C1 | |
| PRT0GS | 02 | RW | | 42 | | ASC10CR2 | 82 | RW | | C2 | |
| PRT0DM2 | 03 | RW | | 43 | | ASC10CR3 | 83 | RW | | C3 | |
| PRT1DR | 04 | RW | | 44 | | ASD11CR0 | 84 | RW | | C4 | |
| PRT1IE | 05 | RW | | 45 | | ASD11CR1 | 85 | RW | | C5 | |
| PRT1GS | 06 | RW | | 46 | | ASD11CR2 | 86 | RW | | C6 | |
| PRT1DM2 | 07 | RW | | 47 | | ASD11CR3 | 87 | RW | | C7 | |
| PRT2DR | 08 | RW | | 48 | | ASC12CR0 | 88 | RW | | C8 | |
| PRT2IE | 09 | RW | | 49 | | ASC12CR1 | 89 | RW | | C9 | |
| PRT2GS | 0A | RW | | 4A | | ASC12CR2 | 8A | RW | | CA | |
| PRT2DM2 | 0B | RW | | 4B | | ASC12CR3 | 8B | RW | | CB | |
| PRT3DR | 0C | RW | | 4C | | ASD13CR0 | 8C | RW | | CC | |
| PRT3IE | 0D | RW | | 4D | | ASD13CR1 | 8D | RW | | CD | |
| PRT3GS | 0E | RW | | 4E | | ASD13CR2 | 8E | RW | | CE | |
| PRT3DM2 | 0F | RW | | 4F | | ASD13CR3 | 8F | RW | | CF | |
| PRT4DR | 10 | RW | | 50 | | ASD20CR0 | 90 | RW | | D0 | |
| PRT4IE | 11 | RW | | 51 | | ASD20CR1 | 91 | RW | | D1 | |
| PRT4GS | 12 | RW | | 52 | | ASD20CR2 | 92 | RW | | D2 | |
| PRT4DM2 | 13 | RW | | 53 | | ASD20CR3 | 93 | RW | | D3 | |
| PRT5DR | 14 | RW | | 54 | | ASC21CR0 | 94 | RW | | D4 | |
| PRT5IE | 15 | RW | | 55 | | ASC21CR1 | 95 | RW | | D5 | |
| PRT5GS | 16 | RW | | 56 | | ASC21CR2 | 96 | RW | I2C_CFG | D6 | RW |
| PRT5DM2 | 17 | RW | | 57 | | ASC21CR3 | 97 | RW | I2C_SCR | D7 | # |
| | 18 | | | 58 | | ASD22CR0 | 98 | RW | I2C_DR | D8 | RW |
| | 19 | | | 59 | | ASD22CR1 | 99 | RW | I2C_MSCR | D9 | # |
| | 1A | | | 5A | | ASD22CR2 | 9A | RW | INT_CLR0 | DA | RW |
| | 1B | | | 5B | | ASD22CR3 | 9B | RW | INT_CLR1 | DB | RW |
| | 1C | | | 5C | | ASC23CR0 | 9C | RW | | DC | |
| | 1D | | | 5D | | ASC23CR1 | 9D | RW | INT_CLR3 | DD | RW |
| | 1E | | | 5E | | ASC23CR2 | 9E | RW | INT_MSK3 | DE | RW |
| | 1F | | | 5F | | ASC23CR3 | 9F | RW | | DF | |
| DBB00DR0 | 20 | # | AMX_IN | 60 | RW | | A0 | | INT_MSK0 | E0 | RW |
| DBB00DR1 | 21 | W | | 61 | | | A1 | | INT_MSK1 | E1 | RW |
| DBB00DR2 | 22 | RW | | 62 | | | A2 | | INT_VC | E2 | RC |
| DBB00CR0 | 23 | # | ARF_CR | 63 | RW | | A3 | | RES_WDT | E3 | W |
| DBB01DR0 | 24 | # | CMP_CR0 | 64 | # | | A4 | | DEC_DH | E4 | RC |
| DBB01DR1 | 25 | W | ASY_CR | 65 | # | | A5 | | DEC_DL | E5 | RC |
| DBB01DR2 | 26 | RW | CMP_CR1 | 66 | RW | | A6 | | DEC_CR0 | E6 | RW |

Blank fields are Reserved and must not be accessed.

Access is bit specific.

Table 10. Register Map Bank 0 Table: User Space (continued)

| Name | Addr (0,Hex) | Access | Name | Addr (0,Hex) | Access | Name | Addr (0,Hex) | Access | Name | Addr (0,Hex) | Access |
|----------|-----------------|--------|----------|-----------------|--------|---------|-----------------|--------|----------|-----------------|--------|
| DBB01CR0 | 27 | # | | 67 | | | A7 | | DEC_CR1 | E7 | RW |
| DCB02DR0 | 28 | # | | 68 | | | A8 | | MUL_X | E8 | W |
| DCB02DR1 | 29 | W | | 69 | | | A9 | | MUL_Y | E9 | W |
| DCB02DR2 | 2A | RW | | 6A | | | AA | | MUL_DH | EA | R |
| DCB02CR0 | 2B | # | | 6B | | | AB | | MUL_DL | EB | R |
| DCB03DR0 | 2C | # | | 6C | | | AC | | ACC_DR1 | EC | RW |
| DCB03DR1 | 2D | W | | 6D | | | AD | | ACC_DR0 | ED | RW |
| DCB03DR2 | 2E | RW | | 6E | | | AE | | ACC_DR3 | EE | RW |
| DCB03CR0 | 2F | # | | 6F | | | AF | | ACC_DR2 | EF | RW |
| DBB10DR0 | 30 | # | ACB00CR3 | 70 | RW | RD10RI | B0 | RW | | F0 | |
| DBB10DR1 | 31 | W | ACB00CR0 | 71 | RW | RD10SYN | B1 | RW | | F1 | |
| DBB10DR2 | 32 | RW | ACB00CR1 | 72 | RW | RD10IS | B2 | RW | | F2 | |
| DBB10CR0 | 33 | # | ACB00CR2 | 73 | RW | RD10LT0 | B3 | RW | | F3 | |
| DBB11DR0 | 34 | # | ACB01CR3 | 74 | RW | RD10LT1 | B4 | RW | | F4 | |
| DBB11DR1 | 35 | W | ACB01CR0 | 75 | RW | RD10RO0 | B5 | RW | | F5 | |
| DBB11DR2 | 36 | RW | ACB01CR1 | 76 | RW | RD10RO1 | B6 | RW | | F6 | |
| DBB11CR0 | 37 | # | ACB01CR2 | 77 | RW | | B7 | | CPU_F | F7 | RL |
| DCB12DR0 | 38 | # | ACB02CR3 | 78 | RW | RD11RI | B8 | RW | | F8 | |
| DCB12DR1 | 39 | W | ACB02CR0 | 79 | RW | RD11SYN | B9 | RW | | F9 | |
| DCB12DR2 | 3A | RW | ACB02CR1 | 7A | RW | RD11IS | BA | RW | | FA | |
| DCB12CR0 | 3B | # | ACB02CR2 | 7B | RW | RD11LT0 | BB | RW | | FB | |
| DCB13DR0 | 3C | # | ACB03CR3 | 7C | RW | RD11LT1 | BC | RW | | FC | |
| DCB13DR1 | 3D | W | ACB03CR0 | 7D | RW | RD11RO0 | BD | RW | | FD | |
| DCB13DR2 | 3E | RW | ACB03CR1 | 7E | RW | RD11RO1 | BE | RW | CPU_SCR1 | FE | # |
| DCB13CR0 | 3F | # | ACB03CR2 | 7F | RW | | BF | | CPU_SCR0 | FF | # |

Blank fields are Reserved and must not be accessed.

Access is bit specific.

Table 11. Register Map Bank 1 Table: Configuration Space

| Name | Addr (1,Hex) | Access | Name | Addr (1,Hex) | Access | Name | Addr (1,Hex) | Access | Name | Addr (1,Hex) | Access |
|---------|-----------------|--------|------|-----------------|--------|----------|-----------------|--------|----------|-----------------|--------|
| PRT0DM0 | 00 | RW | | 40 | | ASC10CR0 | 80 | RW | | C0 | |
| PRT0DM1 | 01 | RW | | 41 | | ASC10CR1 | 81 | RW | | C1 | |
| PRT0IC0 | 02 | RW | | 42 | | ASC10CR2 | 82 | RW | | C2 | |
| PRT0IC1 | 03 | RW | | 43 | | ASC10CR3 | 83 | RW | | C3 | |
| PRT1DM0 | 04 | RW | | 44 | | ASD11CR0 | 84 | RW | | C4 | |
| PRT1DM1 | 05 | RW | | 45 | | ASD11CR1 | 85 | RW | | C5 | |
| PRT1IC0 | 06 | RW | | 46 | | ASD11CR2 | 86 | RW | | C6 | |
| PRT1IC1 | 07 | RW | | 47 | | ASD11CR3 | 87 | RW | | C7 | |
| PRT2DM0 | 08 | RW | | 48 | | ASC12CR0 | 88 | RW | | C8 | |
| PRT2DM1 | 09 | RW | | 49 | | ASC12CR1 | 89 | RW | | C9 | |
| PRT2IC0 | 0A | RW | | 4A | | ASC12CR2 | 8A | RW | | CA | |
| PRT2IC1 | 0B | RW | | 4B | | ASC12CR3 | 8B | RW | | CB | |
| PRT3DM0 | 0C | RW | | 4C | | ASD13CR0 | 8C | RW | | CC | |
| PRT3DM1 | 0D | RW | | 4D | | ASD13CR1 | 8D | RW | | CD | |
| PRT3IC0 | 0E | RW | | 4E | | ASD13CR2 | 8E | RW | | CE | |
| PRT3IC1 | 0F | RW | | 4F | | ASD13CR3 | 8F | RW | | CF | |
| PRT4DM0 | 10 | RW | | 50 | | ASD20CR0 | 90 | RW | GDI_O_IN | D0 | RW |
| PRT4DM1 | 11 | RW | | 51 | | ASD20CR1 | 91 | RW | GDI_E_IN | D1 | RW |
| PRT4IC0 | 12 | RW | | 52 | | ASD20CR2 | 92 | RW | GDI_O_OU | D2 | RW |
| PRT4IC1 | 13 | RW | | 53 | | ASD20CR3 | 93 | RW | GDI_E_OU | D3 | RW |
| PRT5DM0 | 14 | RW | | 54 | | ASC21CR0 | 94 | RW | | D4 | |
| PRT5DM1 | 15 | RW | | 55 | | ASC21CR1 | 95 | RW | | D5 | |
| PRT5IC0 | 16 | RW | | 56 | | ASC21CR2 | 96 | RW | | D6 | |
| PRT5IC1 | 17 | RW | | 57 | | ASC21CR3 | 97 | RW | | D7 | |
| | 18 | | | 58 | | ASD22CR0 | 98 | RW | | D8 | |
| | 19 | | | 59 | | ASD22CR1 | 99 | RW | | D9 | |
| | 1A | | | 5A | | ASD22CR2 | 9A | RW | | DA | |
| | 1B | | | 5B | | ASD22CR3 | 9B | RW | | DB | |
| | 1C | | | 5C | | ASC23CR0 | 9C | RW | | DC | |

Blank fields are Reserved and must not be accessed.

Access is bit specific.

Table 11. Register Map Bank 1 Table: Configuration Space (continued)

| Name | Addr (1,Hex) | Access | Name | Addr (1,Hex) | Access | Name | Addr (1,Hex) | Access | Name | Addr (1,Hex) | Access |
|---------|-----------------|--------|----------|-----------------|--------|----------|-----------------|--------|-----------|-----------------|--------|
| | 1D | | | 5D | | ASC23CR1 | 9D | RW | OSC_GO_EN | DD | RW |
| | 1E | | | 5E | | ASC23CR2 | 9E | RW | OSC_CR4 | DE | RW |
| | 1F | | | 5F | | ASC23CR3 | 9F | RW | OSC_CR3 | DF | RW |
| DBB00FN | 20 | RW | CLK_CR0 | 60 | RW | | A0 | | OSC_CR0 | E0 | RW |
| DBB00IN | 21 | RW | CLK_CR1 | 61 | RW | | A1 | | OSC_CR1 | E1 | RW |
| DBB00OU | 22 | RW | ABF_CR0 | 62 | RW | | A2 | | OSC_CR2 | E2 | RW |
| | 23 | | AMD_CR0 | 63 | RW | | A3 | | VLT_CR | E3 | RW |
| DBB01FN | 24 | RW | | 64 | | | A4 | | VLT_CMP | E4 | R |
| DBB01IN | 25 | RW | | 65 | | | A5 | | | E5 | |
| DBB01OU | 26 | RW | AMD_CR1 | 66 | RW | | A6 | | | E6 | |
| | 27 | | ALT_CR0 | 67 | RW | | A7 | | | E7 | |
| DCB02FN | 28 | RW | ALT_CR1 | 68 | RW | | A8 | | IMO_TR | E8 | W |
| DCB02IN | 29 | RW | CLK_CR2 | 69 | RW | | A9 | | ILO_TR | E9 | W |
| DCB02OU | 2A | RW | | 6A | | | AA | | BDG_TR | EA | RW |
| | 2B | | | 6B | | | AB | | ECO_TR | EB | W |
| DCB03FN | 2C | RW | | 6C | | | AC | | | EC | |
| DCB03IN | 2D | RW | | 6D | | | AD | | | ED | |
| DCB03OU | 2E | RW | | 6E | | | AE | | | EE | |
| | 2F | | | 6F | | | AF | | | EF | |
| DBB10FN | 30 | RW | ACB00CR3 | 70 | RW | RD10RI | B0 | RW | | F0 | |
| DBB10IN | 31 | RW | ACB00CR0 | 71 | RW | RD10SYN | B1 | RW | | F1 | |
| DBB10OU | 32 | RW | ACB00CR1 | 72 | RW | RD10IS | B2 | RW | | F2 | |
| | 33 | | ACB00CR2 | 73 | RW | RD10LT0 | B3 | RW | | F3 | |
| DBB11FN | 34 | RW | ACB01CR3 | 74 | RW | RD10LT1 | B4 | RW | | F4 | |
| DBB11IN | 35 | RW | ACB01CR0 | 75 | RW | RD10RO0 | B5 | RW | | F5 | |
| DBB11OU | 36 | RW | ACB01CR1 | 76 | RW | RD10RO1 | B6 | RW | | F6 | |
| | 37 | | ACB01CR2 | 77 | RW | | B7 | | CPU_F | F7 | RL |
| DCB12FN | 38 | RW | ACB02CR3 | 78 | RW | RD11RI | B8 | RW | | F8 | |
| DCB12IN | 39 | RW | ACB02CR0 | 79 | RW | RD11SYN | B9 | RW | | F9 | |
| DCB12OU | 3A | RW | ACB02CR1 | 7A | RW | RD11IS | BA | RW | | FA | |
| | 3B | | ACB02CR2 | 7B | RW | RD11LT0 | BB | RW | | FB | |
| DCB13FN | 3C | RW | ACB03CR3 | 7C | RW | RD11LT1 | BC | RW | | FC | |
| DCB13IN | 3D | RW | ACB03CR0 | 7D | RW | RD11RO0 | BD | RW | | FD | |
| DCB13OU | 3E | RW | ACB03CR1 | 7E | RW | RD11RO1 | BE | RW | CPU_SCR1 | FE | # |
| | 3F | | ACB03CR2 | 7F | RW | | BF | | CPU_SCR0 | FF | # |

Blank fields are Reserved and must not be accessed.

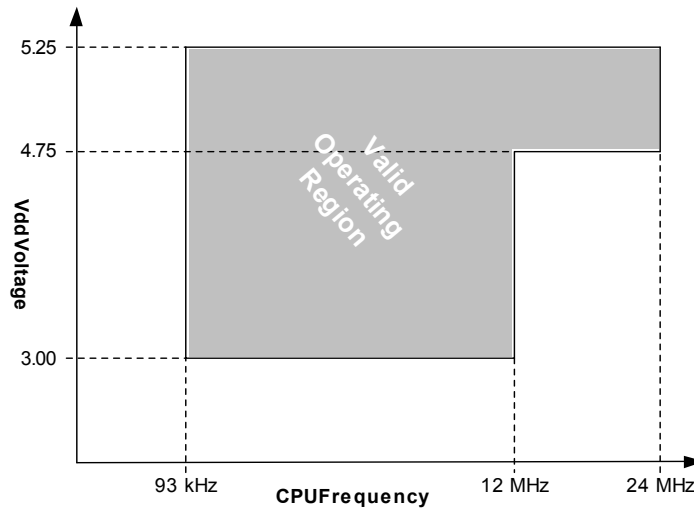
Access is bit specific.

Electrical Specifications

This section presents the DC and AC electrical specifications of the CY8C27x43 PSoC device. For the most up to date electrical specifications, confirm that you have the most recent datasheet by going to the web at <http://www.cypress.com>.

Specifications are valid for $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$ and $T_J \leq 100^{\circ}\text{C}$, except where noted. Specifications for devices running at greater than 12 MHz are valid for $-40^{\circ}\text{C} \leq T_A \leq 70^{\circ}\text{C}$ and $T_J \leq 82^{\circ}\text{C}$.

Figure 10. Voltage versus CPU Frequency



Absolute Maximum Ratings

Exceeding maximum ratings may shorten the useful life of the device. User guidelines are not tested.

Table 12. Absolute Maximum Ratings

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|-----------------------|---|-----------------------|-----|-----------------------|-------|--|
| T _{STG} | Storage temperature | -55 | 25 | +100 | °C | Higher storage temperatures reduce data retention time. Recommended storage temperature is +25 °C ± 25 °C. Extended duration storage temperatures above 65 °C degrade reliability. |
| T _{BAKETEMP} | Bake temperature | – | 125 | See package label | °C | |
| t _{BAKETIME} | Bake time | See package label | – | 72 | Hours | |
| T _A | Ambient temperature with power applied | -40 | – | +85 | °C | |
| V _{DD} | Supply voltage on V _{DD} relative to V _{SS} | -0.5 | – | +6.0 | V | |
| V _{IO} | DC input voltage | V _{SS} – 0.5 | – | V _{DD} + 0.5 | V | |
| V _{IOZ} | DC voltage applied to tristate | V _{SS} – 0.5 | – | V _{DD} + 0.5 | V | |
| I _{MIO} | Maximum current into any port pin | -25 | – | +50 | mA | |
| I _{MAIO} | Maximum current into any port pin configured as analog driver | -50 | – | +50 | mA | |
| ESD | Electrostatic discharge voltage | 2000 | – | – | V | Human body model ESD. |
| LU | Latch-up current | – | – | 200 | mA | |

Operating Temperature

Table 13. Operating Temperature

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|--------|----------------------|-----|-----|------|------|---|
| T_A | Ambient temperature | -40 | – | +85 | °C | |
| T_J | Junction temperature | -40 | – | +100 | °C | The temperature rise from ambient to junction is package specific. See Thermal Impedances on page 50 . The user must limit the power consumption to comply with this requirement. |

DC Electrical Characteristics

DC Chip-Level Specifications

Table 14 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ °C} \leq T_A \leq 85\text{ °C}$, or 3.0 V to 3.6 V and $-40\text{ °C} \leq T_A \leq 85\text{ °C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 14. DC Chip-Level Specifications

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|--------------|---|-------|-------|-------|------|--|
| V_{DD} | Supply voltage | 3.00 | – | 5.25 | V | |
| I_{DD} | Supply current | – | 5 | 8 | mA | Conditions are $V_{DD} = 5.0\text{ V}$, $T_A = 25\text{ °C}$, CPU = 3 MHz, SYSCLK doubler disabled. VC1 = 1.5 MHz, VC2 = 93.75 kHz, VC3 = 93.75 kHz. |
| I_{DD3} | Supply current | – | 3.3 | 6.0 | mA | Conditions are $V_{DD} = 3.3\text{ V}$, $T_A = 25\text{ °C}$, CPU = 3 MHz, SYSCLK doubler disabled. VC1 = 1.5 MHz, VC2 = 93.75 kHz, VC3 = 93.75 kHz. |
| I_{SB} | Sleep (Mode) current with POR, LVD, sleep timer, and WDT. ^[10] | – | 3 | 6.5 | μA | Conditions are with internal slow speed oscillator, $V_{DD} = 3.3\text{ V}$, $-40\text{ °C} \leq T_A \leq 55\text{ °C}$. |
| I_{SBH} | Sleep (Mode) current with POR, LVD, sleep timer, and WDT at high temperature. ^[10] | – | 4 | 25 | μA | Conditions are with internal slow speed oscillator, $V_{DD} = 3.3\text{ V}$, $55\text{ °C} < T_A \leq 85\text{ °C}$. |
| I_{SBXTL} | Sleep (Mode) current with POR, LVD, sleep timer, WDT, and external crystal. ^[10] | – | 4 | 7.5 | μA | Conditions are with properly loaded, 1 μW max, 32.768 kHz crystal. $V_{DD} = 3.3\text{ V}$, $-40\text{ °C} \leq T_A \leq 55\text{ °C}$. |
| I_{SBXTLH} | Sleep (Mode) current with POR, LVD, sleep timer, WDT, and external crystal at high temperature. ^[10] | – | 5 | 26 | μA | Conditions are with properly loaded, 1 μW max, 32.768 kHz crystal. $V_{DD} = 3.3\text{ V}$, $55\text{ °C} < T_A \leq 85\text{ °C}$. |
| V_{REF} | Reference voltage (Bandgap) for Silicon A ^[11] | 1.275 | 1.300 | 1.325 | V | Trimmed for appropriate V_{DD} . |
| V_{REF} | Reference voltage (Bandgap) for Silicon B ^[11] | 1.280 | 1.300 | 1.320 | V | Trimmed for appropriate V_{DD} . |

Notes

10. Standby current includes all functions (POR, LVD, WDT, Sleep Time) needed for reliable system operation. This must be compared with devices that have similar functions enabled.

11. Refer to the [Ordering Information on page 53](#).

DC GPIO Specifications

Table 15 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25°C and are for design guidance only.

Table 15. DC GPIO Specifications

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|-----------|-----------------------------------|----------------|-----|------|-----------|---|
| R_{PU} | Pull-up resistor | 4 | 5.6 | 8 | $k\Omega$ | |
| R_{PD} | Pull-down resistor | 4 | 5.6 | 8 | $k\Omega$ | |
| V_{OH} | High output level | $V_{DD} - 1.0$ | — | — | V | $I_{OH} = 10\text{ mA}$, $V_{DD} = 4.75\text{ to }5.25\text{ V}$ (8 total loads, 4 on even port pins (for example, P0[2], P1[4]), 4 on odd port pins (for example, P0[3], P1[5])). |
| V_{OL} | Low output level | — | — | 0.75 | V | $I_{OL} = 25\text{ mA}$, $V_{DD} = 4.75\text{ to }5.25\text{ V}$ (8 total loads, 4 on even port pins (for example, P0[2], P1[4]), 4 on odd port pins (for example, P0[3], P1[5])). |
| I_{OH} | High-level source current | 10 | — | — | mA | $V_{OH} = V_{DD} - 1.0\text{ V}$, see the limitations of the total current in the note for V_{OH} |
| I_{OL} | Low-level sink current | 25 | — | — | mA | $V_{OL} = 0.75\text{ V}$, see the limitations of the total current in the note for V_{OL} |
| V_{IL} | Input low level | — | — | 0.8 | V | $V_{DD} = 3.0\text{ to }5.25$ |
| V_{IH} | Input high level | 2.1 | — | — | V | $V_{DD} = 3.0\text{ to }5.25$ |
| V_H | Input hysteresis | — | 60 | — | mV | |
| I_{IL} | Input leakage (absolute value) | — | 1 | — | nA | Gross tested to $1\text{ }\mu\text{A}$. |
| C_{IN} | Capacitive load on pins as input | — | 3.5 | 10 | pF | Package and pin dependent. Temp = 25°C . |
| C_{OUT} | Capacitive load on pins as output | — | 3.5 | 10 | pF | Package and pin dependent. Temp = 25°C . |

DC Operational Amplifier Specifications

Table 16 and Table 17 list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25°C and are for design guidance only.

The operational amplifier is a component of both the analog continuous time PSoC blocks and the analog switched cap PSoC blocks. The guaranteed specifications are measured in the analog continuous time PSoC block. Typical parameters apply to 5 V at 25°C and are for design guidance only.

Table 16. 5-V DC Operational Amplifier Specifications

| Symbol | Description | Min | Typ | Max | Units | Notes |
|--------------|--|----------------------------|--|----------------------------------|----------------------------------|---|
| V_{OSOA} | Input offset voltage (absolute value) Power = low, Opamp bias = low Power = low, Opamp bias = high Power = medium, Opamp bias = low Power = medium, Opamp bias = high Power = high, Opamp bias = low Power = high, Opamp bias = high | — — — — — — | 1.6 1.6 1.6 1.6 1.6 1.6 | 10 10 10 10 10 10 | mV mV mV mV mV mV | |
| TCV_{OSOA} | Average input offset voltage drift | — | 4 | 20 | $\mu\text{V}/^{\circ}\text{C}$ | |
| I_{EBOA} | Input leakage current (port 0 analog pins) | — | 20 | — | pA | Gross tested to $1\text{ }\mu\text{A}$. |
| C_{INOA} | Input capacitance (port 0 analog pins) | — | 4.5 | 9.5 | pF | Package and pin dependent. Temp = 25°C |
| V_{CMOA} | Common mode voltage range | 0 | — | V_{DD} | V | The common-mode input voltage range is measured through an analog output buffer. The specification includes the limitations imposed by the characteristics of the analog output buffer. |
| | Common mode voltage range (high power or high Opamp bias) | 0.5 | — | $V_{DD} - 0.5$ | V | |

Table 16. 5-V DC Operational Amplifier Specifications

| Symbol | Description | Min | Typ | Max | Units | Notes |
|----------------------|---|-----------------------|------|------|-------|--|
| CMRR _{OA} | Common mode rejection ratio | | | | | Specification is applicable at both High and Low opamp bias. |
| | Power = low, Opamp bias = high | 60 | — | — | dB | |
| | Power = medium, Opamp bias = high | 60 | — | — | dB | |
| | Power = high, Opamp bias = high | 60 | — | — | dB | |
| G _{OLOA} | Open loop gain | | | | | Specification is applicable at High opamp bias. For Low opamp bias mode, minimum is 60 dB. |
| | Power = low, Opamp bias = high | 60 | — | — | dB | |
| | Power = medium, Opamp bias = high | 60 | — | — | dB | |
| | Power = high, Opamp bias = high | 80 | — | — | dB | |
| V _{OHIGHOA} | High output voltage swing (internal signals) | | | | | |
| | Power = low, Opamp bias = high | V _{DD} – 0.2 | — | — | V | |
| | Power = medium, Opamp bias = high | V _{DD} – 0.2 | — | — | V | |
| | Power = high, Opamp bias = high | V _{DD} – 0.5 | — | — | V | |
| V _{OLOWOA} | Low output voltage swing (internal signals) | | | | | |
| | Power = low, Opamp bias = high | — | — | 0.2 | V | |
| | Power = medium, Opamp bias = high | — | — | 0.2 | V | |
| | Power = high, Opamp bias = high | — | — | 0.5 | V | |
| I _{SOA} | Supply current (including associated AGND buffer) | | | | | |
| | Power = low, Opamp bias = low | — | 150 | 200 | μA | |
| | Power = low, Opamp bias = high | — | 300 | 400 | μA | |
| | Power = medium, Opamp bias = low | — | 600 | 800 | μA | |
| | Power = medium, Opamp bias = high | — | 1200 | 1600 | μA | |
| | Power = high, Opamp bias = low | — | 2400 | 3200 | μA | |
| | Power = high, Opamp bias = high | — | 4600 | 6400 | μA | |
| PSRR _{OA} | Supply voltage rejection ratio | 60 | — | — | dB | V _{SS} ≤ V _{IN} ≤ (V _{DD} – 2.25) or (V _{DD} – 1.25 V) ≤ V _{IN} ≤ V _{DD} . |

Table 17. 3.3-V DC Operational Amplifier Specifications

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|---------------------|--|-----|-----|-----------------------|-------|---|
| V _{OSOA} | Input offset voltage (absolute value) | | | | | Power = high, Opamp bias = high setting is not allowed for 3.3 V V _{DD} operation. |
| | Power = low, Opamp bias = low | — | 1.4 | 10 | mV | |
| | Power = low, Opamp bias = high | — | 1.4 | 10 | mV | |
| | Power = medium, Opamp bias = low | — | 1.4 | 10 | mV | |
| | Power = medium, Opamp bias = high | — | 1.4 | 10 | mV | |
| | Power = high, Opamp bias = low | — | 1.4 | 10 | mV | |
| | Power = high, Opamp bias = high | — | — | — | mV | |
| TCV _{OSOA} | Average input offset voltage drift | — | 7 | 40 | μV/°C | |
| I _{EBOA} | Input leakage current (port 0 analog pins) | — | 20 | — | pA | Gross tested to 1μA. |
| C _{INOA} | Input capacitance (port 0 analog pins) | — | 4.5 | 9.5 | pF | Package and pin dependent. Temp = 25 °C. |
| V _{CMOA} | Common mode voltage range | 0.2 | — | V _{DD} – 0.2 | V | The common-mode input voltage range is measured through an analog output buffer. The specification includes the limitations imposed by the characteristics of the analog output buffer. |
| CMRR _{OA} | Common mode rejection ratio | | | | | Specification is applicable at Low opamp bias. For High bias mode (except High Power, High opamp bias), minimum is 60 dB. |
| | Power = low, Opamp bias = low | 50 | — | — | dB | |
| | Power = medium, Opamp bias = low | 50 | — | — | dB | |
| | Power = high, Opamp bias = low | 50 | — | — | dB | |
| G _{OLOA} | Open loop gain | | | | | Specification is applicable at Low opamp bias. For High opamp bias mode (except High Power, High opamp bias), minimum is 60 dB. |
| | Power = low, Opamp bias = low | 60 | — | — | dB | |
| | Power = medium, Opamp bias = low | 60 | — | — | dB | |
| | Power = high, Opamp bias = low | 80 | — | — | dB | |

Table 17. 3.3-V DC Operational Amplifier Specifications (continued)

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|----------------------|---|-----------------------|------|------|------|--|
| V _{OHIGHOA} | High output voltage swing (internal signals) | | | | | Power = high, Opamp bias = high setting is not allowed for 3.3 V V _{DD} operation. |
| | Power = low, Opamp bias = low | V _{DD} – 0.2 | – | – | V | |
| | Power = medium, Opamp bias = low | V _{DD} – 0.2 | – | – | V | |
| | Power = high, Opamp bias = low | V _{DD} – 0.2 | – | – | V | |
| V _{OLOWOA} | Low output voltage swing (internal signals) | | | | | Power = high, Opamp bias = high setting is not allowed for 3.3 V V _{DD} operation. |
| | Power = low, Opamp bias = low | – | – | 0.2 | V | |
| | Power = medium, Opamp bias = low | – | – | 0.2 | V | |
| | Power = high, Opamp bias = low | – | – | 0.2 | V | |
| I _{SOA} | Supply current (including associated AGND buffer) | | | | | Power = high, Opamp bias = high setting is not allowed for 3.3 V V _{DD} operation. |
| | Power = low, Opamp bias = low | – | 150 | 200 | μA | |
| | Power = low, Opamp bias = high | – | 300 | 400 | μA | |
| | Power = medium, Opamp bias = low | – | 600 | 800 | μA | |
| | Power = medium, Opamp bias = high | – | 1200 | 1600 | μA | |
| | Power = high, Opamp bias = low | – | 2400 | 3200 | μA | |
| | Power = high, Opamp bias = high | – | – | – | μA | |
| PSRR _{OA} | Supply voltage rejection ratio | 50 | 80 | – | dB | V _{SS} ≤ V _{IN} ≤ (V _{DD} – 2.25) or (V _{DD} – 1.25 V) ≤ V _{IN} ≤ V _{DD} . |

DC Low-Power Comparator Specifications

Table 18 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, or 2.4 V to 3.0 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V at 25 °C and are for design guidance only.

Table 18. DC Low-Power Comparator Specifications

| Symbol | Description | Min | Typ | Max | Unit |
|---------------------|--|-----|-----|---------------------|------|
| V _{REFLPC} | Low-power comparator (LPC) reference voltage range | 0.2 | – | V _{DD} – 1 | V |
| I _{SLPC} | LPC supply current | – | 10 | 40 | μA |
| V _{OSLPC} | LPC voltage offset | – | 2.5 | 30 | mV |

DC Analog Output Buffer Specifications

Table 19 and Table 20 on page 24 list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and –40 °C ≤ T_A ≤ 85 °C, or 3.0 V to 3.6 V and –40 °C ≤ T_A ≤ 85 °C, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 19. 5-V DC Analog Output Buffer Specifications

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|----------------------|--|-----------------------------|-----|-----------------------------|-------|-------|
| V _{OSOB} | Input offset voltage (absolute value) | | | | | |
| | Power = low, Opamp bias = low | – | 3 | 19 | mV | |
| | Power = low, Opamp bias = high | – | 3 | 19 | mV | |
| | Power = high, Opamp bias = low | – | 3 | 19 | mV | |
| | Power = high, Opamp bias = high | – | 3 | 19 | mV | |
| TCV _{OSOB} | Average input offset voltage drift | – | 5 | 30 | μV/°C | |
| V _{CMOB} | Common-mode input voltage range | 0.5 | – | V _{DD} – 1.0 | V | |
| R _{OUTOB} | Output resistance | | | | | |
| | Power = low | – | 1 | – | Ω | |
| | Power = high | – | 1 | – | Ω | |
| V _{OHIGHOB} | High output voltage swing (Load = 32 ohms to V _{DD} /2) | | | | | |
| | Power = low | 0.5 × V _{DD} + 1.3 | – | – | V | |
| | Power = high | 0.5 × V _{DD} + 1.3 | – | – | V | |
| V _{OLOWOB} | Low output voltage swing (Load = 32 ohms to V _{DD} /2) | – | – | – | | |
| | Power = low | – | – | 0.5 × V _{DD} – 1.3 | V | |
| | Power = high | – | – | 0.5 × V _{DD} – 1.3 | V | |

Table 19. 5-V DC Analog Output Buffer Specifications (continued)

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|-------------|--|-----|-----|-----|------|--|
| I_{SOB} | Supply current including opamp bias cell (no load) | — | 1.1 | 5.1 | mA | |
| | Power = low | — | 2.6 | 8.8 | mA | |
| | Power = high | — | — | — | — | |
| $PSRR_{OB}$ | Supply voltage rejection ratio | 60 | 64 | — | dB | |
| I_{OMAX} | Maximum output current | — | 40 | — | mA | |
| C_L | Load capacitance | — | — | 200 | pF | This specification applies to the external circuit driven by the analog output buffer. |

Table 20. 3.3-V DC Analog Output Buffer Specifications

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|---------------|---|---------------------------|-----|---------------------------|-------------------|--|
| V_{OSOB} | Input offset voltage (absolute value) | — | 3.2 | 20 | mV | High power setting is not recommended. |
| | Power = low, Opamp bias = low | — | 3.2 | 20 | mV | |
| | Power = low, Opamp bias = high | — | 6 | 25 | mV | |
| | Power = high, Opamp bias = low | — | 6 | 25 | mV | |
| | Power = high, Opamp bias = high | — | 6 | 25 | mV | |
| TCV_{OSOB} | Average input offset voltage drift | — | 9 | 55 | $\mu V/^{\circ}C$ | High power setting is not recommended. |
| | Power = low, Opamp bias = low | — | 9 | 55 | $\mu V/^{\circ}C$ | |
| | Power = low, Opamp bias = high | — | 12 | 70 | $\mu V/^{\circ}C$ | |
| | Power = high, Opamp bias = low | — | 12 | 70 | $\mu V/^{\circ}C$ | |
| | Power = high, Opamp bias = high | — | 12 | 70 | $\mu V/^{\circ}C$ | |
| V_{CMOB} | Common-mode input voltage range | 0.5 | — | $V_{DD} - 1.0$ | V | |
| R_{OUTOB} | Output resistance | — | 1 | — | Ω | |
| | Power = low | — | 1 | — | Ω | |
| $V_{OHIGHOB}$ | High output voltage swing (load = 32 ohms to $V_{DD}/2$) | — | — | — | V | |
| | Power = low | $0.5 \times V_{DD} + 1.0$ | — | — | V | |
| | Power = high | $0.5 \times V_{DD} + 1.0$ | — | — | V | |
| V_{OLOWOB} | Low output voltage swing (load = 32 ohms to $V_{DD}/2$) | — | — | $0.5 \times V_{DD} - 1.0$ | V | |
| | Power = low | — | — | $0.5 \times V_{DD} - 1.0$ | V | |
| | Power = high | — | — | $0.5 \times V_{DD} - 1.0$ | V | |
| I_{SOB} | Supply current including opamp bias cell (no load) | — | 0.8 | 2 | mA | |
| | Power = low | — | 2.0 | 4.3 | mA | |
| | Power = high | — | — | — | — | |
| $PSRR_{OB}$ | Supply voltage rejection ratio | 60 | 64 | — | dB | |
| C_L | Load capacitance | — | — | 200 | pF | This specification applies to the external circuit driven by the analog output buffer. |

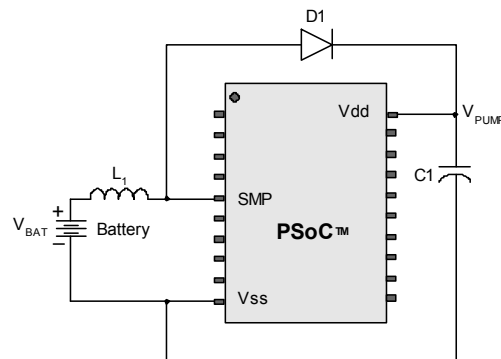
DC Switch Mode Pump Specifications

Table 21 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25°C and are for design guidance only.

Table 21. DC Switch Mode Pump (SMP) Specifications

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|----------------------------------|---|--------|--------|--------|----------|---|
| $V_{\text{PUMP } 5\text{ V}}$ | 5 V output voltage | 4.75 | 5.0 | 5.25 | V | Configured as in Note 12. Average, neglecting ripple. SMP trip voltage is set to 5.0 V. |
| $V_{\text{PUMP } 3\text{ V}}$ | 3 V output voltage | 3.00 | 3.25 | 3.60 | V | Configured as in Note 12. Average, neglecting ripple. SMP trip voltage is set to 3.25 V. |
| I_{PUMP} | Available output current $V_{\text{BAT}} = 1.5\text{ V}$, $V_{\text{PUMP}} = 3.25\text{ V}$ $V_{\text{BAT}} = 1.8\text{ V}$, $V_{\text{PUMP}} = 5.0\text{ V}$ | 8 5 | — — | — — | mA mA | Configured as in Note 12. SMP trip voltage is set to 3.25 V. SMP trip voltage is set to 5.0 V. |
| $V_{\text{BAT } 5\text{ V}}$ | Input voltage range from battery | 1.8 | — | 5.0 | V | Configured as in Note 12. SMP trip voltage is set to 5.0 V. |
| $V_{\text{BAT } 3\text{ V}}$ | Input voltage range from battery | 1.0 | — | 3.3 | V | Configured as in Note 12. SMP trip voltage is set to 3.25 V. |
| V_{BATSTART} | Minimum input voltage from battery to start pump | 1.1 | — | — | V | Configured as in Note 12. |
| $\Delta V_{\text{PUMP_Line}}$ | Line regulation (over V_{BAT} range) | — | 5 | — | % V_O | Configured as in Note 12. V_O is the " V_{DD} Value for PUMP Trip" specified by the VM[2:0] setting in the DC POR and LVD Specification, Table 25 on page 33 . |
| $\Delta V_{\text{PUMP_Load}}$ | Load regulation | — | 5 | — | % V_O | Configured as in Note 12. V_O is the " V_{DD} Value for PUMP Trip" specified by the VM[2:0] setting in the DC POR and LVD Specification, Table 25 on page 33 . |
| $\Delta V_{\text{PUMP_Ripple}}$ | Output voltage ripple (depends on capacitor/load) | — | 100 | — | mVpp | Configured as in Note 12. Load is 5 mA. |
| E_3 | Efficiency | 35 | 50 | — | % | Configured as in Note 12. Load is 5 mA. SMP trip voltage is set to 3.25 V. |
| F_{PUMP} | Switching frequency | — | 1.3 | — | MHz | |
| DC_{PUMP} | Switching duty cycle | — | 50 | — | % | |

Figure 11. Basic Switch Mode Pump Circuit



Note

12. $L_1 = 2\text{ mH}$ inductor, $C_1 = 10\text{ mF}$ capacitor, $D_1 =$ Schottky diode. See [Figure 11](#).

DC Analog Reference Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25°C and are for design guidance only.

The guaranteed specifications are measured through the Analog Continuous Time PSoC blocks. The power levels for AGND refer to the power of the analog continuous time PSoC block. The power levels for RefHi and RefLo refer to the Analog Reference Control register. The limits stated for AGND include the offset error of the AGND buffer local to the Analog Continuous Time PSoC block. Reference control power is high.

Note Avoid using P2[4] for digital signaling when using an analog resource that depends on the Analog Reference. Some coupling of the digital signal may appear on the AGND.

Table 22. 5-V DC Analog Reference Specifications

| Reference ARF_CR [5:3] | Reference Power Settings | Symbol | Reference | Description | Min | Typ | Max | Unit |
|------------------------------|--|--------------------|-----------|------------------------------|----------------------------|----------------------------|----------------------------|------|
| 0b000 | RefPower = high Opamp bias = high | V _{REFHI} | Ref High | V _{DD} /2 + Bandgap | V _{DD} /2 + 1.228 | V _{DD} /2 + 1.290 | V _{DD} /2 + 1.352 | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.078 | V _{DD} /2 – 0.007 | V _{DD} /2 + 0.063 | V |
| | | V _{REFLO} | Ref Low | V _{DD} /2 – Bandgap | V _{DD} /2 – 1.336 | V _{DD} /2 – 1.295 | V _{DD} /2 – 1.250 | V |
| | RefPower = high Opamp bias = low | V _{REFHI} | Ref High | V _{DD} /2 + Bandgap | V _{DD} /2 + 1.224 | V _{DD} /2 + 1.293 | V _{DD} /2 + 1.356 | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.056 | V _{DD} /2 – 0.005 | V _{DD} /2 + 0.043 | V |
| | | V _{REFLO} | Ref Low | V _{DD} /2 – Bandgap | V _{DD} /2 – 1.338 | V _{DD} /2 – 1.298 | V _{DD} /2 – 1.255 | V |
| | RefPower = medium Opamp bias = high | V _{REFHI} | Ref High | V _{DD} /2 + Bandgap | V _{DD} /2 + 1.226 | V _{DD} /2 + 1.293 | V _{DD} /2 + 1.356 | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.057 | V _{DD} /2 – 0.006 | V _{DD} /2 + 0.044 | V |
| | | V _{REFLO} | Ref Low | V _{DD} /2 – Bandgap | V _{DD} /2 – 1.337 | V _{DD} /2 – 1.298 | V _{DD} /2 – 1.256 | V |
| | RefPower = medium Opamp bias = low | V _{REFHI} | Ref High | V _{DD} /2 + Bandgap | V _{DD} /2 + 1.226 | V _{DD} /2 + 1.294 | V _{DD} /2 + 1.359 | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.047 | V _{DD} /2 – 0.004 | V _{DD} /2 + 0.035 | V |
| | | V _{REFLO} | Ref Low | V _{DD} /2 – Bandgap | V _{DD} /2 – 1.338 | V _{DD} /2 – 1.299 | V _{DD} /2 – 1.258 | V |

Note

13. AGND tolerance includes the offsets of the local buffer in the PSoC block.

Table 22. 5-V DC Analog Reference Specifications (continued)

| Reference ARF_CR [5:3] | Reference Power Settings | Symbol | Reference | Description | Min | Typ | Max | Unit |
|------------------------|--|--------------------|-----------|---|----------------------------|----------------------------|----------------------------|------|
| 0b001 | RefPower = high Opamp bias = high | V _{REFHI} | Ref High | P2[4] + P2[6] (P2[4] = V _{DD} /2, P2[6] = 1.3 V) | P2[4] + P2[6] – 0.085 | P2[4] + P2[6] – 0.016 | P2[4] + P2[6] + 0.044 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | – |
| | | V _{REFLO} | Ref Low | P2[4] – P2[6] (P2[4] = V _{DD} /2, P2[6] = 1.3 V) | P2[4] – P2[6] – 0.022 | P2[4] – P2[6] + 0.010 | P2[4] – P2[6] + 0.055 | V |
| | RefPower = high Opamp bias = low | V _{REFHI} | Ref High | P2[4] + P2[6] (P2[4] = V _{DD} /2, P2[6] = 1.3 V) | P2[4] + P2[6] – 0.077 | P2[4] + P2[6] – 0.010 | P2[4] + P2[6] + 0.051 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | – |
| | | V _{REFLO} | Ref Low | P2[4] – P2[6] (P2[4] = V _{DD} /2, P2[6] = 1.3 V) | P2[4] – P2[6] – 0.022 | P2[4] – P2[6] + 0.005 | P2[4] – P2[6] + 0.039 | V |
| | RefPower = medium Opamp bias = high | V _{REFHI} | Ref High | P2[4] + P2[6] (P2[4] = V _{DD} /2, P2[6] = 1.3 V) | P2[4] + P2[6] – 0.070 | P2[4] + P2[6] – 0.010 | P2[4] + P2[6] + 0.050 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | – |
| | | V _{REFLO} | Ref Low | P2[4] – P2[6] (P2[4] = V _{DD} /2, P2[6] = 1.3 V) | P2[4] – P2[6] – 0.022 | P2[4] – P2[6] + 0.005 | P2[4] – P2[6] + 0.039 | V |
| | RefPower = medium Opamp bias = low | V _{REFHI} | Ref High | P2[4] + P2[6] (P2[4] = V _{DD} /2, P2[6] = 1.3 V) | P2[4] + P2[6] – 0.070 | P2[4] + P2[6] – 0.007 | P2[4] + P2[6] + 0.054 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | – |
| | | V _{REFLO} | Ref Low | P2[4] – P2[6] (P2[4] = V _{DD} /2, P2[6] = 1.3 V) | P2[4] – P2[6] – 0.022 | P2[4] – P2[6] + 0.002 | P2[4] – P2[6] + 0.032 | V |
| 0b010 | RefPower = high Opamp bias = high | V _{REFHI} | Ref High | V _{DD} | V _{DD} – 0.037 | V _{DD} – 0.009 | V _{DD} | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.061 | V _{DD} /2 – 0.006 | V _{DD} /2 + 0.047 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.007 | V _{SS} + 0.028 | V |
| | RefPower = high Opamp bias = low | V _{REFHI} | Ref High | V _{DD} | V _{DD} – 0.039 | V _{DD} – 0.006 | V _{DD} | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.049 | V _{DD} /2 – 0.005 | V _{DD} /2 + 0.036 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.005 | V _{SS} + 0.019 | V |
| | RefPower = medium Opamp bias = high | V _{REFHI} | Ref High | V _{DD} | V _{DD} – 0.037 | V _{DD} – 0.007 | V _{DD} | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.054 | V _{DD} /2 – 0.005 | V _{DD} /2 + 0.041 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.006 | V _{SS} + 0.024 | V |
| | RefPower = medium Opamp bias = low | V _{REFHI} | Ref High | V _{DD} | V _{DD} – 0.042 | V _{DD} – 0.005 | V _{DD} | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.046 | V _{DD} /2 – 0.004 | V _{DD} /2 + 0.034 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.004 | V _{SS} + 0.017 | V |

Table 22. 5-V DC Analog Reference Specifications (continued)

| Reference ARF_CR [5:3] | Reference Power Settings | Symbol | Reference | Description | Min | Typ | Max | Unit |
|------------------------------|--|--------------------|-----------|--|---------------|---------------|---------------|------|
| 0b011 | RefPower = high Opamp bias = high | V _{REFHI} | Ref High | 3 × Bandgap | 3.788 | 3.891 | 3.986 | V |
| | | V _{AGND} | AGND | 2 × Bandgap | 2.500 | 2.604 | 3.699 | V |
| | | V _{REFLO} | Ref Low | Bandgap | 1.257 | 1.306 | 1.359 | V |
| | RefPower = high Opamp bias = low | V _{REFHI} | Ref High | 3 × Bandgap | 3.792 | 3.893 | 3.982 | V |
| | | V _{AGND} | AGND | 2 × Bandgap | 2.518 | 2.602 | 2.692 | V |
| | | V _{REFLO} | Ref Low | Bandgap | 1.256 | 1.302 | 1.354 | V |
| | RefPower = medium Opamp bias = high | V _{REFHI} | Ref High | 3 × Bandgap | 3.795 | 3.894 | 3.993 | V |
| | | V _{AGND} | AGND | 2 × Bandgap | 2.516 | 2.603 | 2.698 | V |
| | | V _{REFLO} | Ref Low | Bandgap | 1.256 | 1.303 | 1.353 | V |
| 0b100 | RefPower = high Opamp bias = high | V _{REFHI} | Ref High | 2 × Bandgap + P2[6] (P2[6] = 1.3 V) | 2.495 – P2[6] | 2.586 – P2[6] | 2.657 – P2[6] | V |
| | | V _{AGND} | AGND | 2 × Bandgap | 2.502 | 2.604 | 2.719 | V |
| | | V _{REFLO} | Ref Low | 2 × Bandgap – P2[6] (P2[6] = 1.3 V) | 2.531 – P2[6] | 2.611 – P2[6] | 2.681 – P2[6] | V |
| | RefPower = high Opamp bias = low | V _{REFHI} | Ref High | 2 × Bandgap + P2[6] (P2[6] = 1.3 V) | 2.500 – P2[6] | 2.591 – P2[6] | 2.662 – P2[6] | V |
| | | V _{AGND} | AGND | 2 × Bandgap | 2.519 | 2.602 | 2.693 | V |
| | | V _{REFLO} | Ref Low | 2 × Bandgap – P2[6] (P2[6] = 1.3 V) | 2.530 – P2[6] | 2.605 – P2[6] | 2.666 – P2[6] | V |
| | RefPower = medium Opamp bias = high | V _{REFHI} | Ref High | 2 × Bandgap + P2[6] (P2[6] = 1.3 V) | 2.503 – P2[6] | 2.592 – P2[6] | 2.662 – P2[6] | V |
| | | V _{AGND} | AGND | 2 × Bandgap | 2.517 | 2.603 | 2.698 | V |
| | | V _{REFLO} | Ref Low | 2 × Bandgap – P2[6] (P2[6] = 1.3 V) | 2.529 – P2[6] | 2.606 – P2[6] | 2.665 – P2[6] | V |
| | RefPower = medium Opamp bias = low | V _{REFHI} | Ref High | 2 × Bandgap + P2[6] (P2[6] = 1.3 V) | 2.505 – P2[6] | 2.594 – P2[6] | 2.665 – P2[6] | V |
| | | V _{AGND} | AGND | 2 × Bandgap | 2.525 | 2.602 | 2.685 | V |
| | | V _{REFLO} | Ref Low | 2 × Bandgap – P2[6] (P2[6] = 1.3 V) | 2.528 – P2[6] | 2.603 – P2[6] | 2.661 – P2[6] | V |

Table 22. 5-V DC Analog Reference Specifications (continued)

| Reference ARF_CR [5:3] | Reference Power Settings | Symbol | Reference | Description | Min | Typ | Max | Unit |
|------------------------|--|--------------------|-----------|---|-----------------|-------------------------|-------------------------|------|
| 0b101 | RefPower = high Opamp bias = high | V _{REFHI} | Ref High | P2[4] + Bandgap (P2[4] = V _{DD} /2) | P2[4] + 1.222 | P2[4] + 1.290 | P2[4] + 1.343 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | – |
| | | V _{REFLO} | Ref Low | P2[4] – Bandgap (P2[4] = V _{DD} /2) | P2[4] – 1.331 | P2[4] – 1.295 | P2[4] – 1.254 | V |
| | RefPower = high Opamp bias = low | V _{REFHI} | Ref High | P2[4] + Bandgap (P2[4] = V _{DD} /2) | P2[4] + 1.226 | P2[4] + 1.293 | P2[4] + 1.347 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | – |
| | | V _{REFLO} | Ref Low | P2[4] – Bandgap (P2[4] = V _{DD} /2) | P2[4] – 1.331 | P2[4] – 1.298 | P2[4] – 1.259 | V |
| | RefPower = medium Opamp bias = high | V _{REFHI} | Ref High | P2[4] + Bandgap (P2[4] = V _{DD} /2) | P2[4] + 1.227 | P2[4] + 1.294 | P2[4] + 1.347 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | – |
| | | V _{REFLO} | Ref Low | P2[4] – Bandgap (P2[4] = V _{DD} /2) | P2[4] – 1.331 | P2[4] – 1.298 | P2[4] – 1.259 | V |
| | RefPower = medium Opamp bias = low | V _{REFHI} | Ref High | P2[4] + Bandgap (P2[4] = V _{DD} /2) | P2[4] + 1.228 | P2[4] + 1.295 | P2[4] + 1.349 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | – |
| | | V _{REFLO} | Ref Low | P2[4] – Bandgap (P2[4] = V _{DD} /2) | P2[4] – 1.332 | P2[4] – 1.299 | P2[4] – 1.260 | V |
| 0b110 | RefPower = high Opamp bias = high | V _{REFHI} | Ref High | 2 × Bandgap | 2.535 | 2.598 | 2.644 | V |
| | | V _{AGND} | AGND | Bandgap | 1.227 | 1.305 | 1.398 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.009 | V _{SS} + 0.038 | V |
| | RefPower = high Opamp bias = low | V _{REFHI} | Ref High | 2 × Bandgap | 2.530 | 2.598 | 2.643 | V |
| | | V _{AGND} | AGND | Bandgap | 1.244 | 1.303 | 1.370 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.005 | V _{SS} + 0.024 | V |
| | RefPower = medium Opamp bias = high | V _{REFHI} | Ref High | 2 × Bandgap | 2.532 | 2.598 | 2.644 | V |
| | | V _{AGND} | AGND | Bandgap | 1.239 | 1.304 | 1.380 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.006 | V _{SS} + 0.026 | V |
| | RefPower = medium Opamp bias = low | V _{REFHI} | Ref High | 2 × Bandgap | 2.528 | 2.598 | 2.645 | V |
| | | V _{AGND} | AGND | Bandgap | 1.249 | 1.302 | 1.362 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.004 | V _{SS} + 0.018 | V |
| 0b111 | RefPower = high Opamp bias = high | V _{REFHI} | Ref High | 3.2 × Bandgap | 4.041 | 4.155 | 4.234 | V |
| | | V _{AGND} | AGND | 1.6 × Bandgap | 1.998 | 2.083 | 2.183 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.010 | V _{SS} + 0.038 | V |
| | RefPower = high Opamp bias = low | V _{REFHI} | Ref High | 3.2 × Bandgap | 4.047 | 4.153 | 4.236 | V |
| | | V _{AGND} | AGND | 1.6 × Bandgap | 2.012 | 2.082 | 2.157 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.006 | V _{SS} + 0.024 | V |
| | RefPower = medium Opamp bias = high | V _{REFHI} | Ref High | 3.2 × Bandgap | 4.049 | 4.154 | 4.238 | V |
| | | V _{AGND} | AGND | 1.6 × Bandgap | 2.008 | 2.083 | 2.165 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.006 | V _{SS} + 0.026 | V |
| | RefPower = medium Opamp bias = low | V _{REFHI} | Ref High | 3.2 × Bandgap | 4.047 | 4.154 | 4.238 | V |
| | | V _{AGND} | AGND | 1.6 × Bandgap | 2.016 | 2.081 | 2.150 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.004 | V _{SS} + 0.018 | V |

Table 23. 3.3-V DC Analog Reference Specifications

| Reference ARF_CR [5:3] | Reference Power Settings | Symbol | Reference | Description | Min | Typ | Max | Unit |
|------------------------|--|--------------------|-----------|---|----------------------------|----------------------------|----------------------------|------|
| 0b000 | RefPower = high Opamp bias = high | V _{REFHI} | Ref High | V _{DD} /2 + Bandgap | V _{DD} /2 + 1.225 | V _{DD} /2 + 1.292 | V _{DD} /2 + 1.361 | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.067 | V _{DD} /2 – 0.002 | V _{DD} /2 + 0.063 | V |
| | | V _{REFLO} | Ref Low | V _{DD} /2 – Bandgap | V _{DD} /2 – 1.35 | V _{DD} /2 – 1.293 | V _{DD} /2 – 1.210 | V |
| | RefPower = high Opamp bias = low | V _{REFHI} | Ref High | V _{DD} /2 + Bandgap | V _{DD} /2 + 1.218 | V _{DD} /2 + 1.294 | V _{DD} /2 + 1.370 | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.038 | V _{DD} /2 – 0.001 | V _{DD} /2 + 0.035 | V |
| | | V _{REFLO} | Ref Low | V _{DD} /2 – Bandgap | V _{DD} /2 – 1.329 | V _{DD} /2 – 1.296 | V _{DD} /2 – 1.259 | V |
| | RefPower = medium Opamp bias = high | V _{REFHI} | Ref High | V _{DD} /2 + Bandgap | V _{DD} /2 + 1.221 | V _{DD} /2 + 1.294 | V _{DD} /2 + 1.366 | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.050 | V _{DD} /2 – 0.002 | V _{DD} /2 + 0.046 | V |
| | | V _{REFLO} | Ref Low | V _{DD} /2 – Bandgap | V _{DD} /2 – 1.331 | V _{DD} /2 – 1.296 | V _{DD} /2 – 1.260 | V |
| | RefPower = medium Opamp bias = low | V _{REFHI} | Ref High | V _{DD} /2 + Bandgap | V _{DD} /2 + 1.226 | V _{DD} /2 + 1.295 | V _{DD} /2 + 1.365 | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.028 | V _{DD} /2 – 0.001 | V _{DD} /2 + 0.025 | V |
| | | V _{REFLO} | Ref Low | V _{DD} /2 – Bandgap | V _{DD} /2 – 1.329 | V _{DD} /2 – 1.297 | V _{DD} /2 – 1.262 | V |
| 0b001 | RefPower = high Opamp bias = high | V _{REFHI} | Ref High | P2[4]+P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V) | P2[4] + P2[6] – 0.098 | P2[4] + P2[6] – 0.018 | P2[4] + P2[6] + 0.055 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | – |
| | | V _{REFLO} | Ref Low | P2[4] – P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V) | P2[4] – P2[6] – 0.055 | P2[4] – P2[6] + 0.013 | P2[4] – P2[6] + 0.086 | V |
| | RefPower = high Opamp bias = low | V _{REFHI} | Ref High | P2[4] + P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V) | P2[4] + P2[6] – 0.082 | P2[4] + P2[6] – 0.011 | P2[4] + P2[6] + 0.050 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | – |
| | | V _{REFLO} | Ref Low | P2[4] – P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V) | P2[4] – P2[6] – 0.037 | P2[4] – P2[6] + 0.006 | P2[4] – P2[6] + 0.054 | V |
| | RefPower = medium Opamp bias = high | V _{REFHI} | Ref High | P2[4] + P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V) | P2[4] + P2[6] – 0.079 | P2[4] + P2[6] – 0.012 | P2[4] + P2[6] + 0.047 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | – |
| | | V _{REFLO} | Ref Low | P2[4]–P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V) | P2[4] – P2[6] – 0.038 | P2[4] – P2[6] + 0.006 | P2[4] – P2[6] + 0.057 | V |
| | RefPower = medium Opamp bias = low | V _{REFHI} | Ref High | P2[4]+P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V) | P2[4] + P2[6] – 0.080 | P2[4] + P2[6] – 0.008 | P2[4] + P2[6] + 0.055 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | – |
| | | V _{REFLO} | Ref Low | P2[4]–P2[6] (P2[4] = V _{DD} /2, P2[6] = 0.5 V) | P2[4] – P2[6] – 0.032 | P2[4] – P2[6] + 0.003 | P2[4] – P2[6] + 0.042 | V |

Table 23. 3.3-V DC Analog Reference Specifications

| Reference ARF_CR [5:3] | Reference Power Settings | Symbol | Reference | Description | Min | Typ | Max | Unit |
|------------------------|--|--------------------|-----------|---|----------------------------|----------------------------|----------------------------|------|
| 0b010 | RefPower = high Opamp bias = high | V _{REFHI} | Ref High | V _{DD} | V _{DD} – 0.06 | V _{DD} – 0.010 | V _{DD} | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.05 | V _{DD} /2 – 0.002 | V _{DD} /2 + 0.040 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.009 | V _{SS} + 0.056 | V |
| | RefPower = high Opamp bias = low | V _{REFHI} | Ref High | V _{DD} | V _{DD} – 0.060 | V _{DD} – 0.006 | V _{DD} | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.028 | V _{DD} /2 – 0.001 | V _{DD} /2 + 0.025 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.005 | V _{SS} + 0.034 | V |
| | RefPower = medium Opamp bias = high | V _{REFHI} | Ref High | V _{DD} | V _{DD} – 0.058 | V _{DD} – 0.008 | V _{DD} | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.037 | V _{DD} /2 – 0.002 | V _{DD} /2 + 0.033 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.007 | V _{SS} + 0.046 | V |
| | RefPower = medium Opamp bias = low | V _{REFHI} | Ref High | V _{DD} | V _{DD} – 0.057 | V _{DD} – 0.006 | V _{DD} | V |
| | | V _{AGND} | AGND | V _{DD} /2 | V _{DD} /2 – 0.025 | V _{DD} /2 – 0.001 | V _{DD} /2 + 0.022 | V |
| | | V _{REFLO} | Ref Low | V _{SS} | V _{SS} | V _{SS} + 0.004 | V _{SS} + 0.030 | V |
| 0b011 | All power settings. Not allowed for 3.3 V | – | – | – | – | – | – | – |
| 0b100 | All power settings. Not allowed for 3.3 V | – | – | – | – | – | – | – |
| 0b101 | RefPower = high Opamp bias = high | V _{REFHI} | Ref High | P2[4] + Bandgap (P2[4] = V _{DD} /2) | P2[4] + 1.213 | P2[4] + 1.291 | P2[4] + 1.367 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | V |
| | | V _{REFLO} | Ref Low | P2[4] – Bandgap (P2[4] = V _{DD} /2) | P2[4] – 1.333 | P2[4] – 1.294 | P2[4] – 1.208 | V |
| | RefPower = high Opamp bias = low | V _{REFHI} | Ref High | P2[4] + Bandgap (P2[4] = V _{DD} /2) | P2[4] + 1.217 | P2[4] + 1.294 | P2[4] + 1.368 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | V |
| | | V _{REFLO} | Ref Low | P2[4] – Bandgap (P2[4] = V _{DD} /2) | P2[4] – 1.320 | P2[4] – 1.296 | P2[4] – 1.261 | V |
| | RefPower = medium Opamp bias = high | V _{REFHI} | Ref High | P2[4] + Bandgap (P2[4] = V _{DD} /2) | P2[4] + 1.217 | P2[4] + 1.294 | P2[4] + 1.369 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | V |
| | | V _{REFLO} | Ref Low | P2[4] – Bandgap (P2[4] = V _{DD} /2) | P2[4] – 1.322 | P2[4] – 1.297 | P2[4] – 1.262 | V |
| | RefPower = medium Opamp bias = low | V _{REFHI} | Ref High | P2[4] + Bandgap (P2[4] = V _{DD} /2) | P2[4] + 1.219 | P2[4] + 1.295 | P2[4] + 1.37 | V |
| | | V _{AGND} | AGND | P2[4] | P2[4] | P2[4] | P2[4] | V |
| | | V _{REFLO} | Ref Low | P2[4] – Bandgap (P2[4] = V _{DD} /2) | P2[4] – 1.324 | P2[4] – 1.297 | P2[4] – 1.262 | V |

Table 23. 3.3-V DC Analog Reference Specifications

| Reference ARF_CR [5:3] | Reference Power Settings | Symbol | Reference | Description | Min | Typ | Max | Unit |
|------------------------|--|--------------------|-----------|-----------------|-----------------|-------------------------|-------------------------|------|
| 0b110 | RefPower = high Opamp bias = high | V _{REFHI} | Ref High | 2 × Bandgap | 2.507 | 2.598 | 2.698 | V |
| | | V _{AGND} | AGND | Bandgap | 1.203 | 1.307 | 1.424 | V |
| | | V _{REFLO} | Ref Low | V _{ss} | V _{ss} | V _{ss} + 0.012 | V _{ss} + 0.067 | V |
| | RefPower = high Opamp bias = low | V _{REFHI} | Ref High | 2 × Bandgap | 2.516 | 2.598 | 2.683 | V |
| | | V _{AGND} | AGND | Bandgap | 1.241 | 1.303 | 1.376 | V |
| | | V _{REFLO} | Ref Low | V _{ss} | V _{ss} | V _{ss} + 0.007 | V _{ss} + 0.040 | V |
| | RefPower = medium Opamp bias = high | V _{REFHI} | Ref High | 2 × Bandgap | 2.510 | 2.599 | 2.693 | V |
| | | V _{AGND} | AGND | Bandgap | 1.240 | 1.305 | 1.374 | V |
| | | V _{REFLO} | Ref Low | V _{ss} | V _{ss} | V _{ss} + 0.008 | V _{ss} + 0.048 | V |
| | RefPower = medium Opamp bias = low | V _{REFHI} | Ref High | 2 × Bandgap | 2.515 | 2.598 | 2.683 | V |
| | | V _{AGND} | AGND | Bandgap | 1.258 | 1.302 | 1.355 | V |
| | | V _{REFLO} | Ref Low | V _{ss} | V _{ss} | V _{ss} + 0.005 | V _{ss} + 0.03 | V |
| 0b111 | All power settings. Not allowed for 3.3 V | — | — | — | — | — | — | — |

DC Analog PSoC Block Specifications

Table 24 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 24. DC Analog PSoC Block Specifications

| Symbol | Description | Min | Typ | Max | Unit |
|-----------------|---------------------------------------|-----|------|-----|------|
| R _{CT} | Resistor unit value (continuous time) | — | 12.2 | — | kΩ |
| C _{SC} | Capacitor unit value (switch cap) | — | 80 | — | fF |

DC POR and LVD Specifications

Table 25 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Note The bits PORLEV and VM in the following table refer to bits in the VLT_CR register. See the *PSoC Programmable System-on-Chip Technical Reference Manual* for more information on the VLT_CR register.

Table 25. DC POR and LVD Specifications

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|--|---|--|--|--|--------------------------------------|---|
| V _{PPOR0R} V _{PPOR1R} V _{PPOR2R} | V _{DD} value for PPOR trip (positive ramp) PORLEV[1:0] = 00b PORLEV[1:0] = 01b PORLEV[1:0] = 10b | – – – | 2.91 4.39 4.55 | – – – | V V V | V _{DD} must be greater than or equal to 2.5 V during startup, reset from the XRES pin, or reset from watchdog. |
| V _{PPOR0} V _{PPOR1} V _{PPOR2} | V _{DD} value for PPOR trip (negative ramp) PORLEV[1:0] = 00b PORLEV[1:0] = 01b PORLEV[1:0] = 10b | – – – | 2.82 4.39 4.55 | – – – | V V V | |
| V _{PH0} V _{PH1} V _{PH2} | PPOR hysteresis PORLEV[1:0] = 00b PORLEV[1:0] = 01b PORLEV[1:0] = 10b | – – – | 92 0 0 | – – – | mV mV mV | |
| V _{LVD0} V _{LVD1} V _{LVD2} V _{LVD3} V _{LVD4} V _{LVD5} V _{LVD6} V _{LVD7} | V _{DD} value for LVD trip VM[2:0] = 000b VM[2:0] = 001b VM[2:0] = 010b VM[2:0] = 011b VM[2:0] = 100b VM[2:0] = 101b VM[2:0] = 110b VM[2:0] = 111b | 2.86 2.96 3.07 3.92 4.39 4.55 4.63 4.72 | 2.92 3.02 3.13 4.00 4.48 4.64 4.73 4.81 | 2.98 ^[14] 3.08 3.20 4.08 4.57 4.74 ^[15] 4.82 4.91 | V V V V V V V V | |
| V _{PUMP0} V _{PUMP1} V _{PUMP2} V _{PUMP3} V _{PUMP4} V _{PUMP5} V _{PUMP6} V _{PUMP7} | V _{DD} value for PUMP trip VM[2:0] = 000b VM[2:0] = 001b VM[2:0] = 010b VM[2:0] = 011b VM[2:0] = 100b VM[2:0] = 101b VM[2:0] = 110b VM[2:0] = 111b | 2.96 3.03 3.18 4.11 4.55 4.63 4.72 4.90 | 3.02 3.10 3.25 4.19 4.64 4.73 4.82 5.00 | 3.08 3.16 3.32 4.28 4.74 4.82 4.91 5.10 | V V V V V V V V | |

Notes

14. Always greater than 50 mV above PPOR (PORLEV = 00) for falling supply.
 15. Always greater than 50 mV above PPOR (PORLEV = 10) for falling supply.

DC Programming Specifications

Table 26 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 26. DC Programming Specifications

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|-----------------------|--|------------------------|-----|-----------------|--------|---|
| V_{DDP} | V_{DD} for programming and erase | 4.5 | 5 | 5.5 | V | This specification applies to the functional requirements of external programmer tools. |
| $V_{DDL V}$ | Low V_{DD} for verify | 3 | 3.1 | 3.2 | V | This specification applies to the functional requirements of external programmer tools. |
| $V_{DDH V}$ | High V_{DD} for verify | 5.1 | 5.2 | 5.3 | V | This specification applies to the functional requirements of external programmer tools. |
| $V_{DDIWRITE}$ | Supply voltage for flash write operation | 3 | | 5.25 | V | This specification applies to this device when it is executing internal flash writes. |
| I_{DDP} | Supply current during programming or verify | – | 5 | 25 | mA | |
| V_{ILP} | Input low voltage during programming or verify | – | – | 0.8 | V | |
| V_{IHP} | Input high voltage during programming or verify | 2.2 | – | – | V | |
| I_{ILP} | Input current when applying V_{ILP} to P1[0] or P1[1] during programming or verify | – | – | 0.2 | mA | Driving internal pull-down resistor. |
| I_{IHP} | Input current when applying V_{IHP} to P1[0] or P1[1] during programming or verify | – | – | 1.5 | mA | Driving internal pull-down resistor. |
| V_{OLV} | Output low voltage during programming or verify | – | – | $V_{SS} + 0.75$ | V | |
| V_{OHV} | Output high voltage during programming or verify | $V_{DD} - 1.0$ | – | V_{DD} | V | |
| Flash _{ENPB} | Flash endurance (per block) | 50,000 ^[16] | – | – | Cycles | Erase/write cycles per block. |
| Flash _{ENT} | Flash endurance (total) ^[17] | 1,800,000 | – | – | Cycles | Erase/write cycles. |
| Flash _{DR} | Flash data retention | 10 | – | – | Years | |

DC I²C Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25 °C and are for design guidance only.

Table 27. DC I²C Specifications

| Parameter | Description | Min | Typ | Max | Units | Notes |
|-----------------------------|------------------|---------------------|-----|----------------------|-------|--|
| V_{ILI2C} ^[18] | Input low level | – | – | $0.3 \times V_{DD}$ | V | $3.0\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ |
| | | – | – | $0.25 \times V_{DD}$ | V | $4.75\text{ V} \leq V_{DD} \leq 5.25\text{ V}$ |
| V_{IHI2C} ^[18] | Input high level | $0.7 \times V_{DD}$ | – | – | V | $3.0\text{ V} \leq V_{DD} \leq 5.25\text{ V}$ |

Notes

16. The 50,000 cycle flash endurance per block is only guaranteed if the flash is operating within one voltage range. Voltage ranges are 3.0 V to 3.6 V and 4.75 V to 5.25 V.

17. A maximum of $36 \times 50,000$ block endurance cycles is allowed. This may be balanced between operations on 36×1 blocks of 50,000 maximum cycles each, 36×2 blocks of 25,000 maximum cycles each, or 36×4 blocks of 12,500 maximum cycles each (to limit the total number of cycles to $36 \times 50,000$ and that no single block ever sees more than 50,000 cycles).

For the full industrial range, you must employ a temperature sensor user module (FlashTemp) and feed the result to the temperature argument before writing.

Refer to the Flash APIs application note [Design Aids – Reading and Writing PSoC® Flash – AN2015](#) for more information.

18. All GPIOs meet the DC GPIO V_{IL} and V_{IH} specifications found in the DC GPIO specifications sections. The I²C GPIO pins also meet the above specs.

AC Electrical Characteristics

AC Chip-Level Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25°C and are for design guidance only.

Table 28. AC Chip-Level Specifications

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|--------------------------|---|--------|--------|--------------------------|---------------|---|
| F _{IMO} | Internal main oscillator (IMO) frequency | 23.4 | 24 | 24.6 ^[19] | MHz | Trimmed. Utilizing factory trim values. |
| F _{CPU1} | CPU frequency (5 V nominal) | 0.0914 | 24 | 24.6 ^[19] | MHz | Trimmed. Utilizing factory trim values. SLIMO mode = 0. |
| F _{CPU2} | CPU frequency (3.3 V nominal) | 0.0914 | 12 | 12.3 ^[20] | MHz | Trimmed. Utilizing factory trim values. SLIMO mode = 0. |
| F _{48M} | Digital PSoC block frequency | 0 | 48 | 49.2 ^[19, 21] | MHz | Refer to AC Digital Block Specifications on page 40 . |
| F _{24M} | Digital PSoC block frequency | 0 | 24 | 24.6 ^[21] | MHz | |
| F _{32K1} | Internal low speed oscillator (ILO) frequency | 15 | 32 | 64 | kHz | |
| F _{32K2} | External crystal oscillator | – | 32.768 | – | kHz | Accuracy is capacitor and crystal dependent. 50% duty cycle. |
| F _{32K_U} | ILO untrimmed frequency | 5 | – | 100 | kHz | After a reset and before the m8c starts to run, the ILO is not trimmed. See the System Resets section of the PSoC Technical Reference Manual for details on timing this |
| F _{PLL} | PLL frequency | – | 23.986 | – | MHz | Multiple (x732) of crystal frequency. |
| t _{PLLSLEW} | PLL lock time | 0.5 | – | 10 | ms | |
| t _{PLLSLEWSLOW} | PLL lock time for low gain setting | 0.5 | – | 50 | ms | |
| t _{OS} | External crystal oscillator startup to 1% | – | 1700 | 2620 | ms | |
| t _{OSACC} | External crystal oscillator startup to 100 ppm | – | 2800 | 3800 | ms | The crystal oscillator frequency is within 100 ppm of its final value by the end of the t _{OSACC} period. Correct operation assumes a properly loaded 1 μW maximum drive level 32.768 kHz crystal. 3.0 V $\leq V_{DD} \leq 5.5$ V, $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$. |
| t _{XRST} | External reset pulse width | 10 | – | – | μs | |
| DC _{24M} | 24 MHz duty cycle | 40 | 50 | 60 | % | |
| DC _{ILO} | ILO duty cycle | 20 | 50 | 80 | % | |
| Step _{24M} | 24 MHz trim step size | – | 50 | – | kHz | |
| t _{POWERUP} | Time from end of POR to CPU executing code | – | 16 | 100 | ms | wer-up from 0 V. See the System Resets section of the PSoC Technical Reference Manual . |
| F _{out48M} | 48 MHz output frequency | 46.8 | 48.0 | 49.2 ^[19, 20] | MHz | Trimmed. Utilizing factory trim values. |
| F _{MAX} | Maximum frequency of signal on row input or row output. | – | – | 12.3 | MHz | |
| SR _{POWER_UP} | Power supply slew rate | – | – | 250 | V/ms | V _{DD} slew rate during power-up. |

Notes

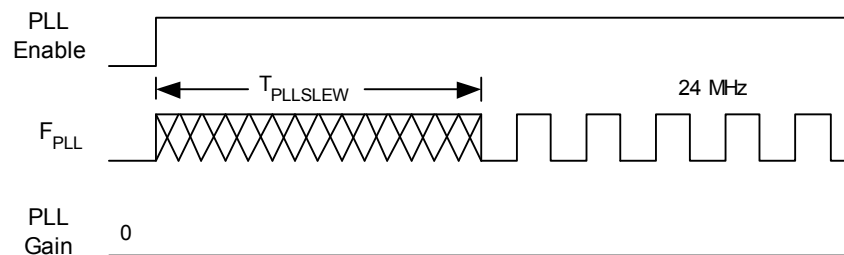
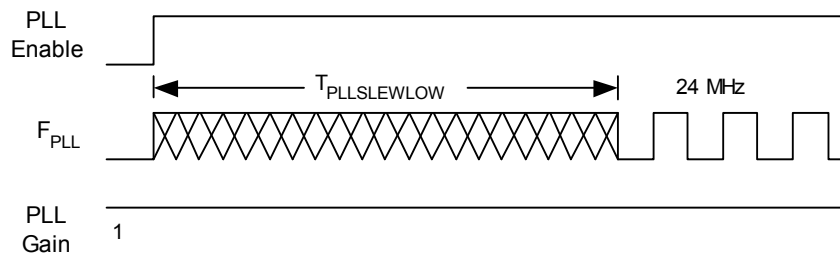
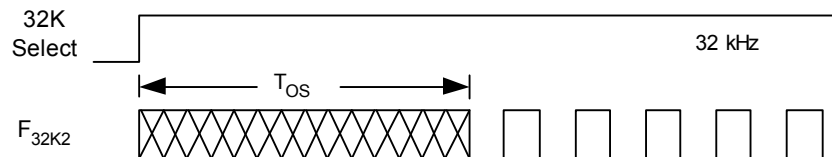
19. 4.75 V $< V_{DD} < 5.25$ V.

20. 3.0 V $< V_{DD} < 3.6$ V. See application note [Adjusting PSoC® Trims for 3.3 V and 2.7 V Operation – AN2012](#) for information on trimming for operation at 3.3 V.

21. See the individual user module datasheets for information on maximum frequencies for user modules.

Table 28. AC Chip-Level Specifications (continued)

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|--------------------------|--|-----|-----|------|------|--------|
| tjit_IMO ^[22] | 24 MHz IMO cycle-to-cycle jitter (RMS) | – | 200 | 700 | ps | N = 32 |
| | 24 MHz IMO long term N cycle-to-cycle jitter (RMS) | – | 300 | 900 | | |
| | 24 MHz IMO period jitter (RMS) | – | 100 | 400 | | |
| tjit_PLL ^[22] | 24 MHz IMO cycle-to-cycle jitter (RMS) | – | 200 | 800 | ps | N = 32 |
| | 24 MHz IMO long term N cycle-to-cycle jitter (RMS) | – | 300 | 1200 | | |
| | 24 MHz IMO period jitter (RMS) | – | 100 | 700 | | |

Figure 12. PLL Lock Timing Diagram

Figure 13. PLL Lock for Low Gain Setting Timing Diagram

Figure 14. External Crystal Oscillator Startup Timing Diagram

Note

 22. Refer to Cypress Jitter Specifications application note, [Understanding Datasheet Jitter Specifications for Cypress Timing Products – AN5054](#) for more information.

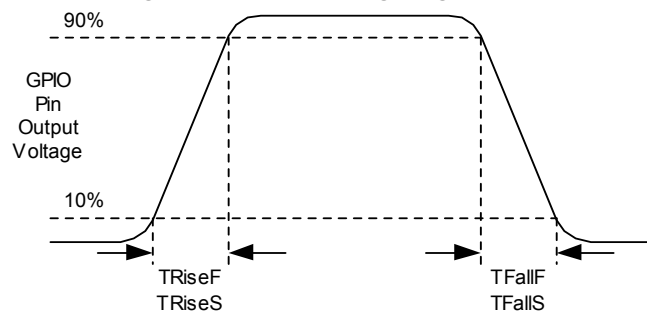
AC GPIO Specifications

Table 29 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25°C and are for design guidance only.

Table 29. AC GPIO Specifications

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|--------------------|---|-----|-----|-----|------|---|
| F_{GPIO} | GPIO operating frequency | 0 | — | 12 | MHz | Normal strong mode |
| t_{RiseF} | Rise time, normal strong mode, $\text{Cload} = 50 \text{ pF}$ | 3 | — | 18 | ns | $V_{\text{DD}} = 4.5 \text{ to } 5.25 \text{ V}$, 10% to 90% |
| t_{FallF} | Fall time, normal strong mode, $\text{Cload} = 50 \text{ pF}$ | 2 | — | 18 | ns | $V_{\text{DD}} = 4.5 \text{ to } 5.25 \text{ V}$, 10% to 90% |
| t_{RiseS} | Rise time, slow strong mode, $\text{Cload} = 50 \text{ pF}$ | 10 | 27 | — | ns | $V_{\text{DD}} = 3 \text{ to } 5.25 \text{ V}$, 10% to 90% |
| t_{FallS} | Fall time, slow strong mode, $\text{Cload} = 50 \text{ pF}$ | 10 | 22 | — | ns | $V_{\text{DD}} = 3 \text{ to } 5.25 \text{ V}$, 10% to 90% |

Figure 15. GPIO Timing Diagram



AC Operational Amplifier Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25°C and are for design guidance only.

Settling times, slew rates, and gain bandwidth are based on the Analog Continuous Time PSoC block.

Power = high and Opamp bias = high is not supported at 3.3 V.

Table 30. 5-V AC Operational Amplifier Specifications

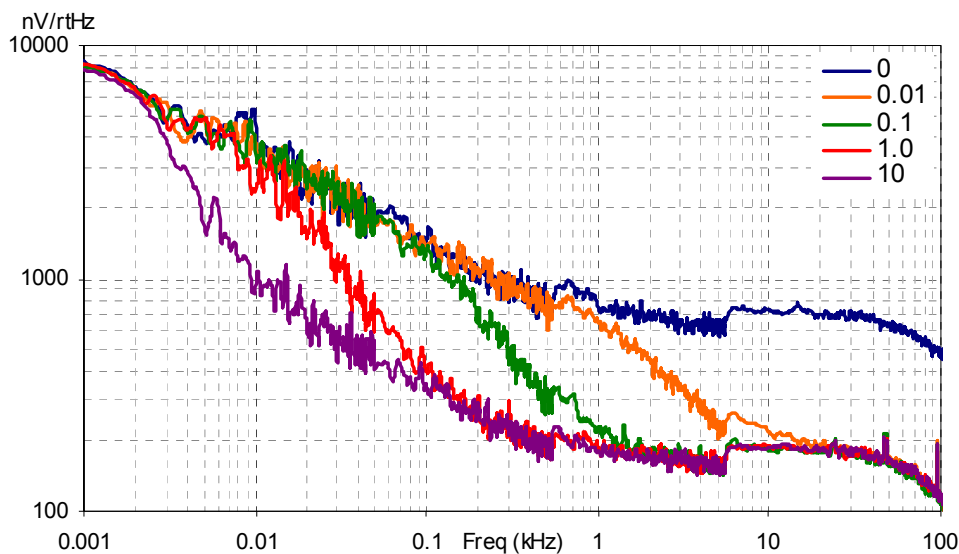
| Symbol | Description | Min | Typ | Max | Unit |
|--------------------------|--|--------------------|-------------|---------------------|--|
| t_{ROA} | Rising settling time from 80% of ΔV to 0.1% of ΔV (10 pF load, Unity Gain) Power = low, Opamp bias = low Power = medium, Opamp bias = high Power = high, Opamp bias = high | — — — | — — — | 3.9 0.72 0.62 | μs μs μs |
| t_{SOA} | Falling settling time from 20% of ΔV to 0.1% of ΔV (10 pF load, Unity Gain) Power = low, Opamp bias = low Power = medium, Opamp bias = high Power = high, Opamp bias = high | — — — | — — — | 5.9 0.92 0.72 | μs μs μs |
| SR_{ROA} | Rising slew rate (20% to 80%) (10 pF load, Unity Gain) Power = low, Opamp bias = low Power = medium, Opamp bias = high Power = high, Opamp bias = high | 0.15 1.7 6.5 | — — — | — — — | $\text{V}/\mu\text{s}$ $\text{V}/\mu\text{s}$ $\text{V}/\mu\text{s}$ |
| SR_{FOA} | Falling slew rate (20% to 80%) (10 pF load, Unity Gain) Power = low, Opamp bias = low Power = medium, Opamp bias = high Power = high, Opamp bias = high | 0.01 0.5 4.0 | — — — | — — — | $\text{V}/\mu\text{s}$ $\text{V}/\mu\text{s}$ $\text{V}/\mu\text{s}$ |
| BW_{OA} | Gain bandwidth product Power = low, Opamp bias = low Power = medium, Opamp bias = high Power = high, Opamp bias = high | 0.75 3.1 5.4 | — — — | — — — | MHz MHz MHz |
| E_{NOA} | Noise at 1 kHz (Power = medium, Opamp bias = high) | — | 100 | — | nV/rt-Hz |

Table 31. 3.3-V AC Operational Amplifier Specifications

| Symbol | Description | Min | Typ | Max | Units |
|------------|---|-------------|--------|--------------|--------------------------|
| t_{ROA} | Rising settling time from 80% of ΔV to 0.1% of ΔV (10 pF load, Unity Gain) Power = low, Opamp bias = low Power = low, Opamp bias = high | — — | — — | 3.92 0.72 | μs μs |
| t_{SOA} | Falling settling time from 20% of ΔV to 0.1% of ΔV (10 pF load, Unity Gain) Power = low, Opamp bias = low Power = medium, Opamp bias = high | — — | — — | 5.41 0.72 | μs μs |
| SR_{ROA} | Rising slew rate (20% to 80%)(10 pF load, Unity Gain) Power = low, Opamp bias = low Power = medium, Opamp bias = high | 0.31 2.7 | — — | — — | V/ μs V/ μs |
| SR_{FOA} | Falling slew rate (20% to 80%)(10 pF load, Unity Gain) Power = low, Opamp bias = low Power = medium, Opamp bias = high | 0.24 1.8 | — — | — — | V/ μs V/ μs |
| BW_{OA} | Gain bandwidth product Power = low, Opamp bias = low Power = medium, Opamp bias = high | 0.67 2.8 | — — | — — | MHz MHz |
| E_{NOA} | Noise at 1 kHz (Power = medium, Opamp bias = high) | — | 100 | — | nV/rt-Hz |

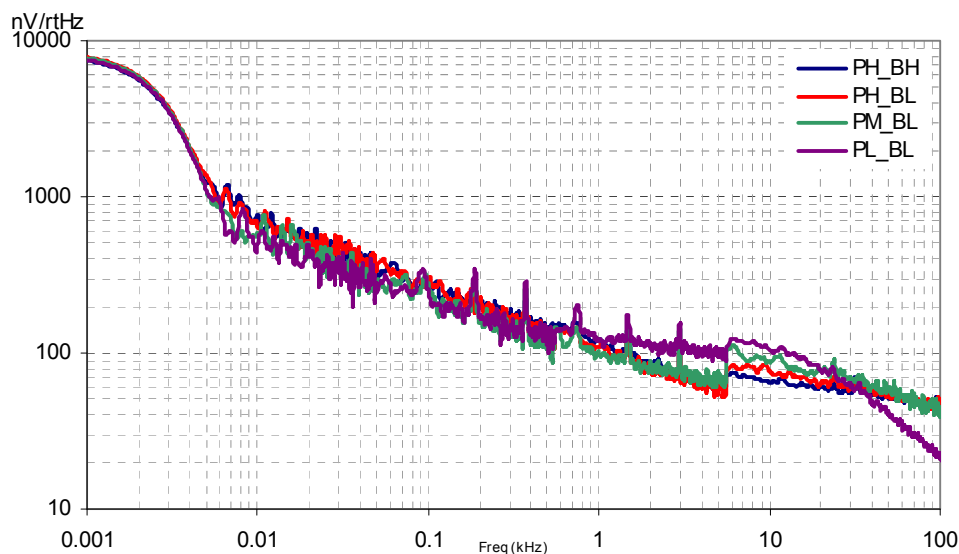
When bypassed by a capacitor on P2[4], the noise of the analog ground signal distributed to each block is reduced by a factor of up to 5 (14 dB). This is at frequencies above the corner frequency defined by the on-chip 8.1 K resistance and the external capacitor.

Figure 16. Typical AGND Noise with P2[4] Bypass



At low frequencies, the opamp noise is proportional to $1/f$, power independent, and determined by device geometry. At high frequencies, increased power level reduces the noise spectrum level.

Figure 17. Typical Opamp Noise



AC Low-Power Comparator Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, 3.0 V to 3.6 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, or 2.4 V to 3.0 V and $-40\text{ }^{\circ}\text{C} \leq T_A \leq 85\text{ }^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V at $25\text{ }^{\circ}\text{C}$ and are for design guidance only.

Table 32. AC Low-Power Comparator Specifications

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|------------|-------------------|-----|-----|-----|---------------|--|
| t_{RLPC} | LPC response time | — | — | 50 | μs | $\geq 50\text{ mV}$ overdrive comparator reference set within V_{REFLPC} . |

AC Digital Block Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25°C and are for design guidance only.

Table 33. AC Digital Block Specifications

| Function | Description | Min | Typ | Max | Unit | Notes |
|-------------------|--|--------------------|-----|------|------|---|
| All functions | Block input clock frequency | | | | | |
| | $V_{DD} \geq 4.75\text{ V}$ | – | – | 49.2 | MHz | |
| | $V_{DD} < 4.75\text{ V}$ | – | – | 24.6 | MHz | |
| Timer | Input clock frequency | | | | | |
| | No capture, $V_{DD} \geq 4.75\text{ V}$ | – | – | 49.2 | MHz | |
| | No capture, $V_{DD} < 4.75\text{ V}$ | – | – | 24.6 | MHz | |
| | With capture | – | – | 24.6 | MHz | |
| | Capture pulse width | 50 ^[23] | – | – | ns | |
| Counter | Input clock frequency | | | | | |
| | No enable input, $V_{DD} \geq 4.75\text{ V}$ | – | – | 49.2 | MHz | |
| | No enable input, $V_{DD} < 4.75\text{ V}$ | – | – | 24.6 | MHz | |
| | With enable input | – | – | 24.6 | MHz | |
| | Enable input pulse width | 50 ^[23] | – | – | ns | |
| Dead Band | Kill pulse width | | | | | |
| | Asynchronous restart mode | 20 | – | – | ns | |
| | Synchronous restart mode | 50 ^[23] | – | – | ns | |
| | Disable mode | 50 ^[23] | – | – | ns | |
| | Input clock frequency | | | | | |
| | $V_{DD} \geq 4.75\text{ V}$ | – | – | 49.2 | MHz | |
| | $V_{DD} < 4.75\text{ V}$ | – | – | 24.6 | MHz | |
| CRCPRS (PRS Mode) | Input clock frequency | | | | | |
| | $V_{DD} \geq 4.75\text{ V}$ | – | – | 49.2 | MHz | |
| | $V_{DD} < 4.75\text{ V}$ | – | – | 24.6 | MHz | |
| CRCPRS (CRC Mode) | Input clock frequency | – | – | 24.6 | MHz | |
| SPIM | Input clock frequency | – | – | 8.2 | MHz | The SPI serial clock (SCLK) frequency is equal to the input clock frequency divided by 2. |
| SPIS | Input clock (SCLK) frequency | – | – | 4.1 | MHz | The input clock is the SPI SCLK in SPIS mode. |
| | Width of SS_negated between transmissions | 50 ^[23] | – | – | ns | |
| Transmitter | Input clock frequency | | | | | The baud rate is equal to the input clock frequency divided by 8. |
| | $V_{DD} \geq 4.75\text{ V}$, 2 stop bits | – | – | 49.2 | MHz | |
| | $V_{DD} \geq 4.75\text{ V}$, 1 stop bit | – | – | 24.6 | MHz | |
| | $V_{DD} < 4.75\text{ V}$ | – | – | 24.6 | MHz | |
| Receiver | Input clock frequency | | | | | The baud rate is equal to the input clock frequency divided by 8. |
| | $V_{DD} \geq 4.75\text{ V}$, 2 stop bits | – | – | 49.2 | MHz | |
| | $V_{DD} \geq 4.75\text{ V}$, 1 stop bit | – | – | 24.6 | MHz | |
| | $V_{DD} < 4.75\text{ V}$ | – | – | 24.6 | MHz | |

Note

23. 50 ns minimum input pulse width is based on the input synchronizers running at 24 MHz (42 ns nominal period).

AC Analog Output Buffer Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25°C and are for design guidance only.

Table 34. 5-V AC Analog Output Buffer Specifications

| Symbol | Description | Min | Typ | Max | Unit |
|--------------------------|---|--------------|--------|------------|--|
| t_{ROB} | Rising settling time to 0.1%, 1 V Step, 100 pF load Power = low Power = high | — — | — — | 2.5 2.5 | μs μs |
| t_{SOB} | Falling settling time to 0.1%, 1 V Step, 100 pF load Power = low Power = high | — — | — — | 2.2 2.2 | μs μs |
| SR_{ROB} | Rising slew rate (20% to 80%), 1 V Step, 100 pF load Power = low Power = high | 0.65 0.65 | — — | — — | $\text{V}/\mu\text{s}$ $\text{V}/\mu\text{s}$ |
| SR_{FOB} | Falling slew rate (80% to 20%), 1 V Step, 100 pF load Power = low Power = high | 0.65 0.65 | — — | — — | $\text{V}/\mu\text{s}$ $\text{V}/\mu\text{s}$ |
| BW_{OB} | Small signal bandwidth, 20 mV _{pp} , 3 dB BW, 100 pF load Power = low Power = high | 0.8 0.8 | — — | — — | MHz MHz |
| BW_{OB} | Large signal bandwidth, 1 V _{pp} , 3 dB BW, 100 pF load Power = low Power = high | 300 300 | — — | — — | kHz kHz |

Table 35. 3.3-V AC Analog Output Buffer Specifications

| Symbol | Description | Min | Typ | Max | Unit |
|--------------------------|---|------------|--------|------------|--|
| t_{ROB} | Rising settling time to 0.1%, 1 V Step, 100 pF load Power = low Power = high | — — | — — | 3.8 3.8 | μs μs |
| t_{SOB} | Falling settling time to 0.1%, 1 V Step, 100 pF load Power = low Power = high | — — | — — | 2.6 2.6 | μs μs |
| SR_{ROB} | Rising slew rate (20% to 80%), 1 V Step, 100 pF load Power = low Power = high | 0.5 0.5 | — — | — — | $\text{V}/\mu\text{s}$ $\text{V}/\mu\text{s}$ |
| SR_{FOB} | Falling slew rate (80% to 20%), 1 V Step, 100 pF load Power = low Power = high | 0.5 0.5 | — — | — — | $\text{V}/\mu\text{s}$ $\text{V}/\mu\text{s}$ |
| BW_{OB} | Small signal bandwidth, 20m V _{pp} , 3 dB BW, 100 pF load Power = low Power = high | 0.7 0.7 | — — | — — | MHz MHz |
| BW_{OB} | Large signal bandwidth, 1 V _{pp} , 3 dB BW, 100 pF load Power = low Power = high | 200 200 | — — | — — | kHz kHz |

AC External Clock Specifications

The following tables list guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25°C and are for design guidance only.

Table 36. 5-V AC External Clock Specifications

| Symbol | Description | Min | Typ | Max | Unit |
|---------------------|------------------------|-------|-----|------|------|
| F _{OSCEXT} | Frequency | 0.093 | – | 24.6 | MHz |
| – | High period | 20.6 | – | 5300 | ns |
| – | Low period | 20.6 | – | – | ns |
| – | Power-up IMO to switch | 150 | – | – | μs |

Table 37. 3.3-V AC External Clock Specifications

| Symbol | Description | Min | Typ | Max | Unit |
|---------------------|---|-------|-----|------|------|
| F _{OSCEXT} | Frequency with CPU clock divide by 1 ^[24] | 0.093 | – | 12.3 | MHz |
| F _{OSCEXT} | Frequency with CPU clock divide by 2 or greater ^[25] | 0.186 | – | 24.6 | MHz |
| – | High period with CPU clock divide by 1 | 41.7 | – | 5300 | ns |
| – | Low period with CPU clock divide by 1 | 41.7 | – | – | ns |
| – | Power-up IMO to switch | 150 | – | – | μs |

AC Programming Specifications

The following table lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25°C and are for design guidance only.

Table 38. AC Programming Specifications

| Symbol | Description | Min | Typ | Max | Unit | Notes |
|---------------------------|--|-----|-----|---------------------|------|--|
| t _{RSCLK} | Rise time of SCLK | 1 | – | 20 | ns | |
| t _{FSCLK} | Fall time of SCLK | 1 | – | 20 | ns | |
| t _{SSCLK} | Data setup time to falling edge of SCLK | 40 | – | – | ns | |
| t _{HSCLK} | Data hold time from falling edge of SCLK | 40 | – | – | ns | |
| F _{SCLK} | Frequency of SCLK | 0 | – | 8 | MHz | |
| t _{ERASEB} | Flash erase time (Block) | – | 30 | – | ms | |
| t _{WRITE} | Flash block write time | – | 10 | – | ms | |
| t _{DSCLK} | Data out delay from falling edge of SCLK | – | – | 45 | ns | V _{DD} > 3.6 |
| t _{DSCLK3} | Data out delay from falling edge of SCLK | – | – | 50 | ns | 3.0 ≤ V _{DD} ≤ 3.6 |
| t _{ERASEALL} | Flash erase time (Bulk) | – | 95 | – | ms | Erase all Blocks and protection fields at once |
| t _{PROGRAM_HOT} | Flash block erase + flash block write time | – | – | 80 ^[26] | ms | 0 °C ≤ T _j ≤ 100 °C |
| t _{PROGRAM_COLD} | Flash block erase + flash block write time | – | – | 160 ^[26] | ms | –40 °C ≤ T _j ≤ 0 °C |

Notes

24. Maximum CPU frequency is 12 MHz at 3.3 V. With the CPU clock divider set to 1, the external clock must adhere to the maximum frequency and duty cycle requirements.

25. If the frequency of the external clock is greater than 12 MHz, the CPU clock divider must be set to 2 or greater. In this case, the CPU clock divider ensures that the fifty percent duty cycle requirement is met.

26. For the full industrial range, you must employ a temperature sensor user module (FlashTemp) and feed the result to the temperature argument before writing. Refer to the Flash APIs application note [Design Aids – Reading and Writing PSoC® Flash – AN2015](#) for more information.

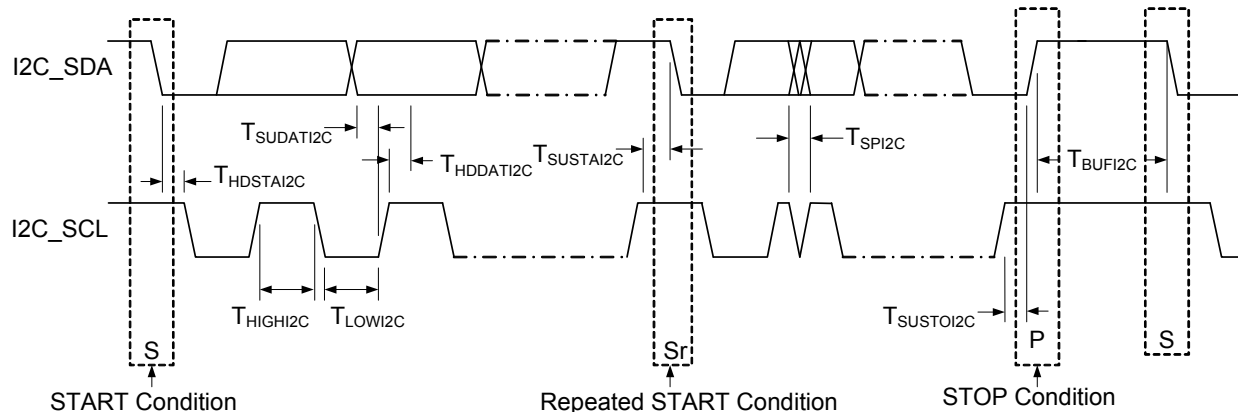
AC I²C Specifications

Table 39 lists guaranteed maximum and minimum specifications for the voltage and temperature ranges: 4.75 V to 5.25 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, or 3.0 V to 3.6 V and $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, respectively. Typical parameters apply to 5 V and 3.3 V at 25°C and are for design guidance only.

Table 39. AC Characteristics of the I²C SDA and SCL Pins

| Symbol | Description | Standard Mode | | Fast Mode | | Unit |
|------------------------------|--|---------------|-----|---------------------|-----|---------------|
| | | Min | Max | Min | Max | |
| $F_{\text{SCL}2\text{C}}$ | SCL clock frequency | 0 | 100 | 0 | 400 | kHz |
| $t_{\text{HDSTA}2\text{C}}$ | Hold time (repeated) start condition. After this period, the first clock pulse is generated. | 4.0 | — | 0.6 | — | μs |
| $t_{\text{LOW}2\text{C}}$ | Low period of the SCL clock | 4.7 | — | 1.3 | — | μs |
| $t_{\text{HIGH}2\text{C}}$ | High period of the SCL clock | 4.0 | — | 0.6 | — | μs |
| $t_{\text{SUSTA}2\text{C}}$ | Set up time for a repeated start condition | 4.7 | — | 0.6 | — | μs |
| $t_{\text{HDDAT}2\text{C}}$ | Data hold time | 0 | — | 0 | — | μs |
| $t_{\text{SUDAT}2\text{C}}$ | Data set up time | 250 | — | 100 ^[27] | — | ns |
| $t_{\text{SUSTOI}2\text{C}}$ | Set up time for stop condition | 4.0 | — | 0.6 | — | μs |
| $t_{\text{BUFI}2\text{C}}$ | Bus-free time between a stop and start condition | 4.7 | — | 1.3 | — | μs |
| $t_{\text{SPI}2\text{C}}$ | Pulse width of spikes are suppressed by the input filter. | — | — | 0 | 50 | ns |

Figure 18. Definition for Timing for Fast/Standard Mode on the I²C Bus



Note

27. A Fast-Mode I²C-bus device can be used in a Standard-Mode I²C-bus system, but the requirement $t_{\text{SU:DAT}} \geq 250 \text{ ns}$ must then be met. This is automatically the case if the device does not stretch the LOW period of the SCL signal. If such device does stretch the LOW period of the SCL signal, it must output the next data bit to the SDA line $t_{\text{rmax}} + t_{\text{SU:DAT}} = 1000 + 250 = 1250 \text{ ns}$ (according to the Standard-Mode I²C-bus specification) before the SCL line is released.

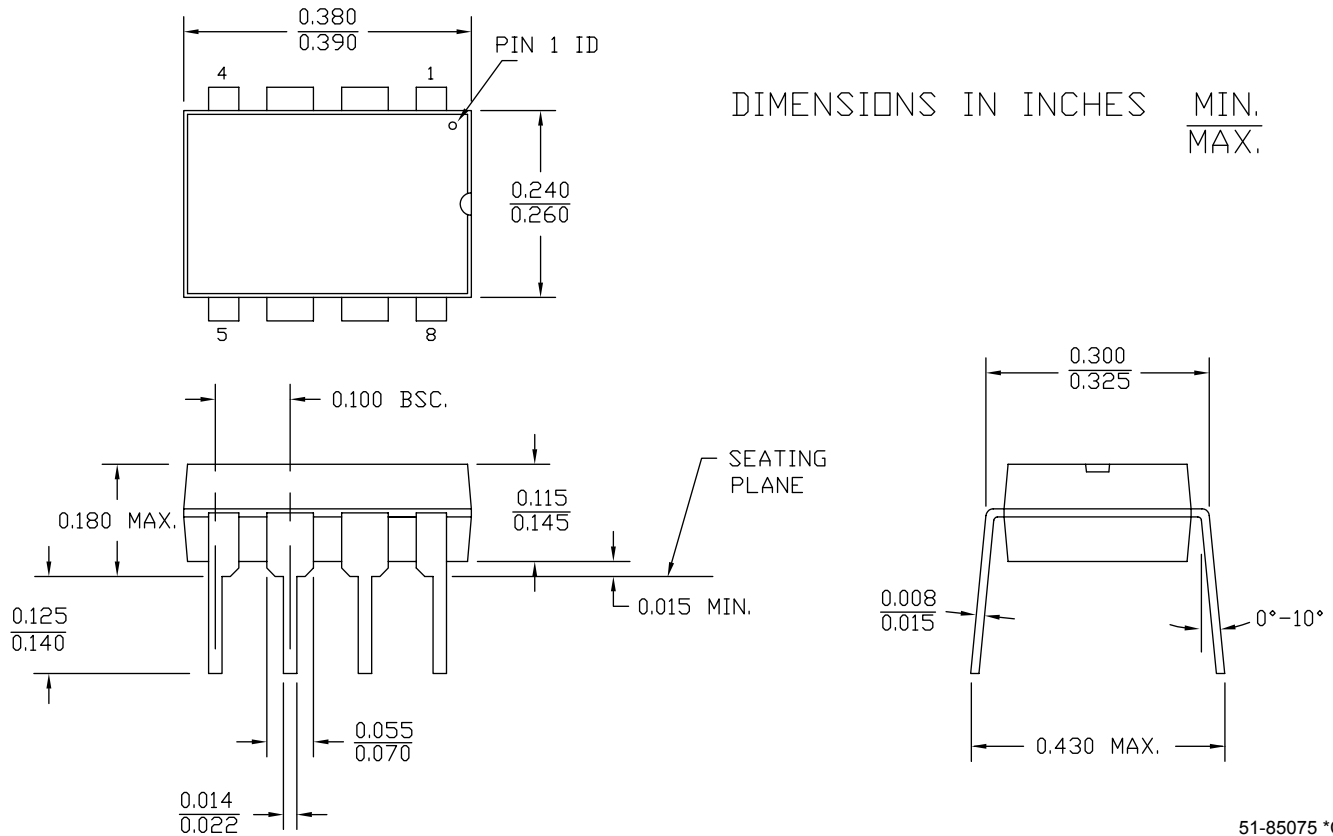
Packaging Information

This section illustrates the packaging specifications for the CY8C27x43 PSoC device, along with the thermal impedances for each package and the typical package capacitance on crystal pins.

Important Note Emulation tools may require a larger area on the target PCB than the chip's footprint. For a detailed description of the emulation tools' dimensions, refer to the emulator pod drawings at <http://www.cypress.com/design/MR10161>.

Packaging Dimensions

Figure 19. 8-pin (300-Mil) PDIP



Technical drawing of a 20-pin DIP package showing top, side, and cross-sectional views with dimensions in millimeters.

Top View Dimensions:

- Pin 10 to Pin 1: 7.50 MIN., 8.10 MAX.
- Pin 11 to Pin 20: 7.00 MIN., 7.40 MAX.
- Pin 1 ID: 1.14 DIA.
- Pin 1 to Pin 20: 1.14 DIA.

Side View Dimensions:

- Seating Plane: 0.10 MAX.
- Pin 10 to Pin 1: 2.00 MAX.
- Pin 11 to Pin 20: 0.05 MIN., 0.21 MAX.
- Pin 1 to Pin 20: 0.22 MIN., 0.38 MAX.
- Pin 1 to Pin 20: 0.65 BSC.

Cross-sectional View Dimensions:

- Gauge Plane: 0.25 MIN.
- Pin 1 to Pin 20: 0.55 MIN., 0.95 MAX.
- Pin 1 to Pin 20: 1.25 REF.
- Pin 1 to Pin 20: 5.00 MIN., 5.60 MAX.
- Pin 1 to Pin 20: 0° MIN., 0°-8° MAX.

51-85077 *E

Figure 21. 20-pin (300-Mil) Molded SOIC

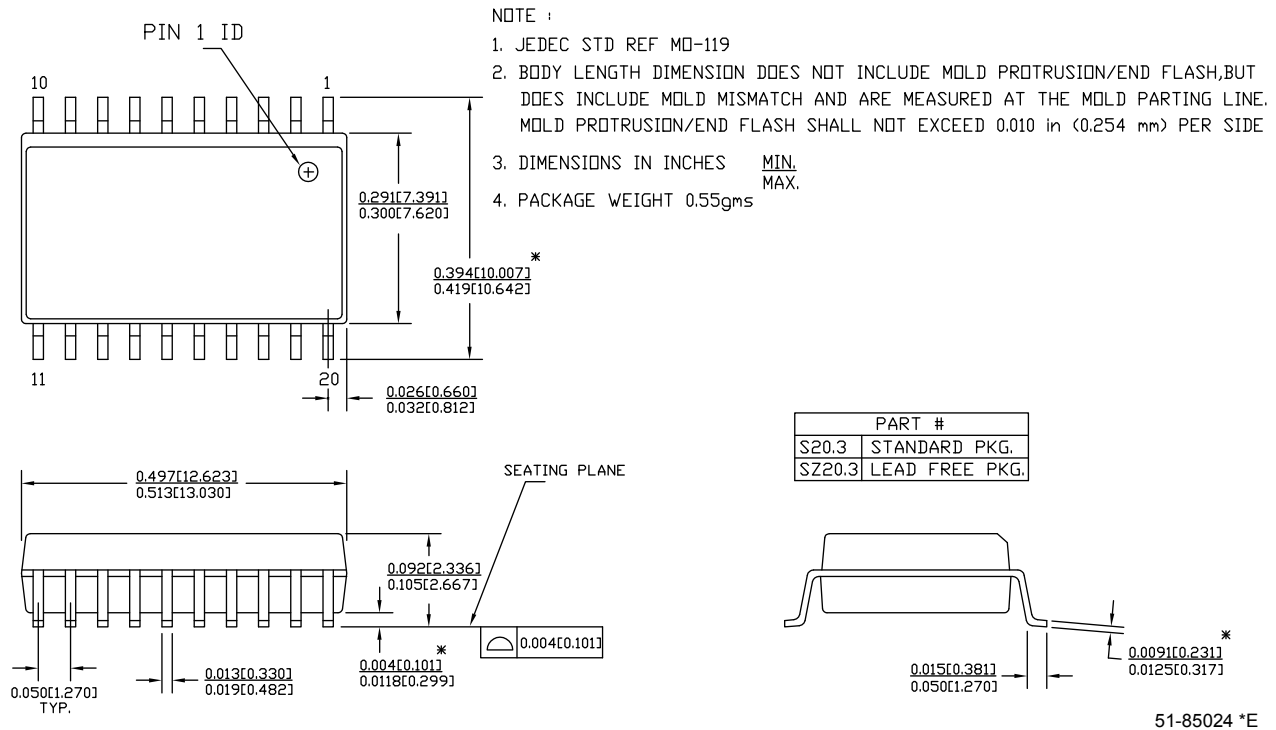
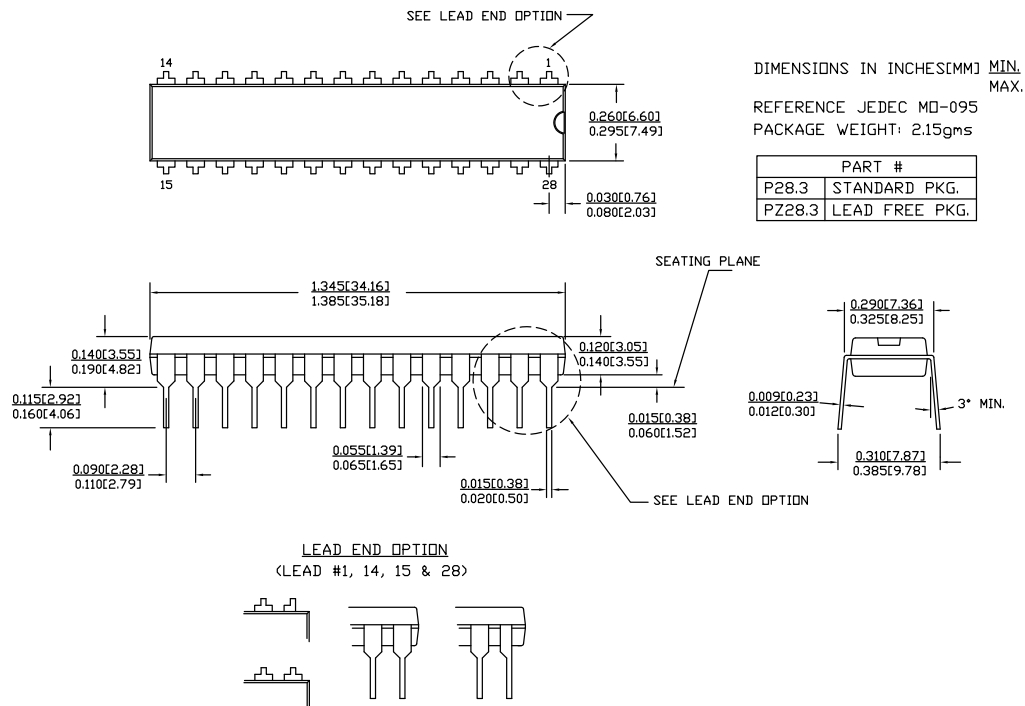


Figure 22. 28-pin (300-Mil) Molded DIP



[illegible]

NOTE :

1. JEDEC STD REF MO-119
2. BODY LENGTH DIMENSION DOES NOT INCLUDE MOLD PROTRUSION/END FLASH,BUT DOES INCLUDE MOLD MISMATCH AND ARE MEASURED AT THE MOLD PARTING LINE. MOLD PROTRUSION/END FLASH SHALL NOT EXCEED 0.010 in (0.254 mm) PER SIDE
3. DIMENSIONS IN INCHES MIN.
MAX.
4. PACKAGE WEIGHT 0.85gms

Top view dimensions: 14, 1, PIN 1 ID, 0.291[7.39], 0.300[7.62], 0.394[10.01] *, 0.419[10.64], 0.026[0.66], 0.032[0.81], 28, 15.

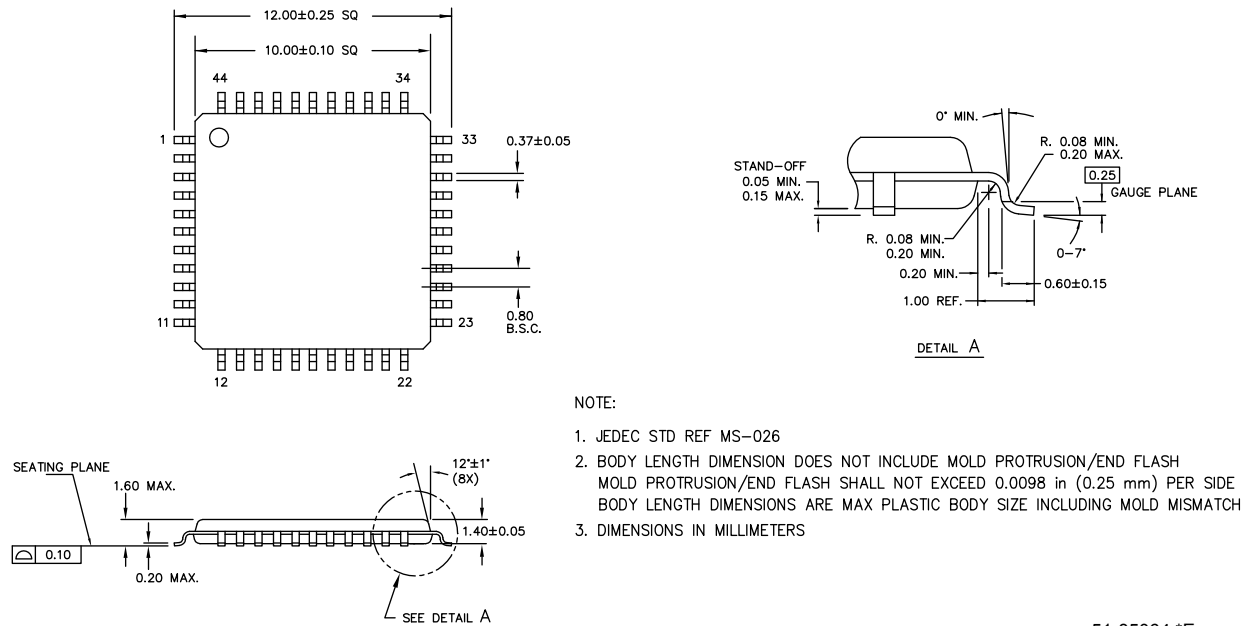
Side view dimensions: 0.697[17.70], 0.713[18.11], SEATING PLANE, 0.092[2.33], 0.105[2.67], 0.013[0.33], 0.019[0.48], 0.050[1.27] TYP., 0.004[0.10] *, 0.0118[0.30].

| PART # | |
|--------|----------------|
| S28.3 | STANDARD PKG. |
| SZ28.3 | LEAD FREE PKG. |

Cross-section dimensions: 0.015[0.38], 0.050[1.27], 0.0091[0.23] *, 0.0125[3.17].

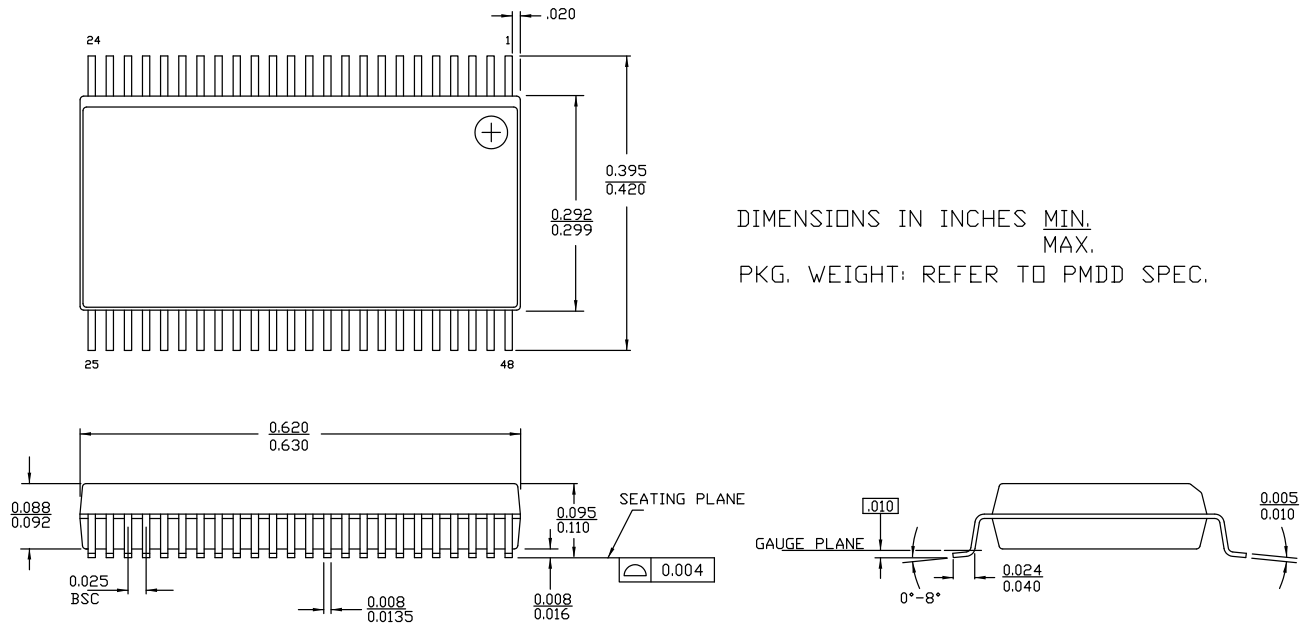
51-85026 *F

Figure 25. 44-pin TQFP



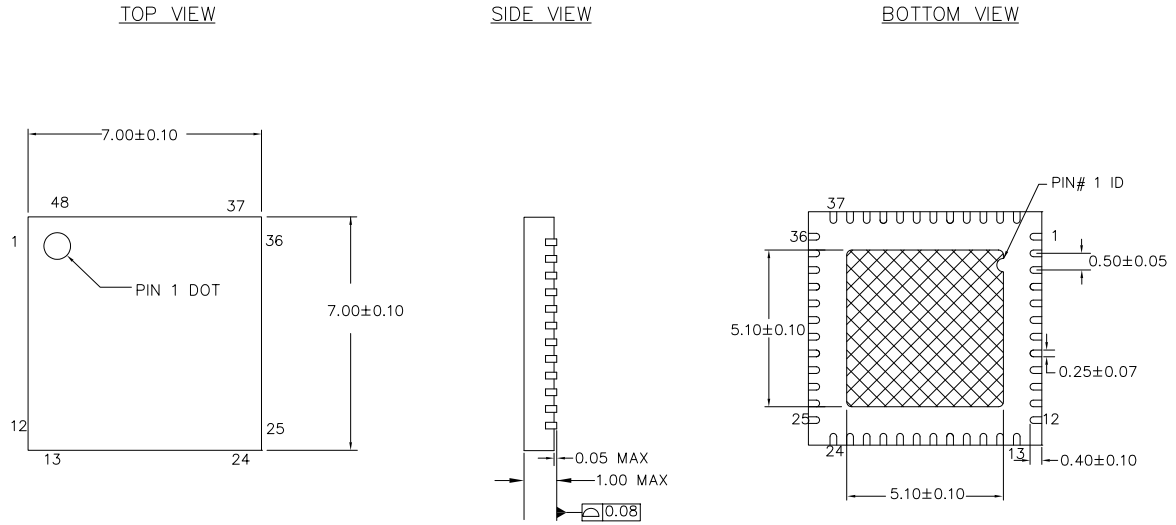
51-85064 *E

Figure 26. 48-pin (300-Mil) SSOP



51-85061 *F

Figure 27. 48-pin QFN 7 × 7 × 1 mm (Sawn Type)

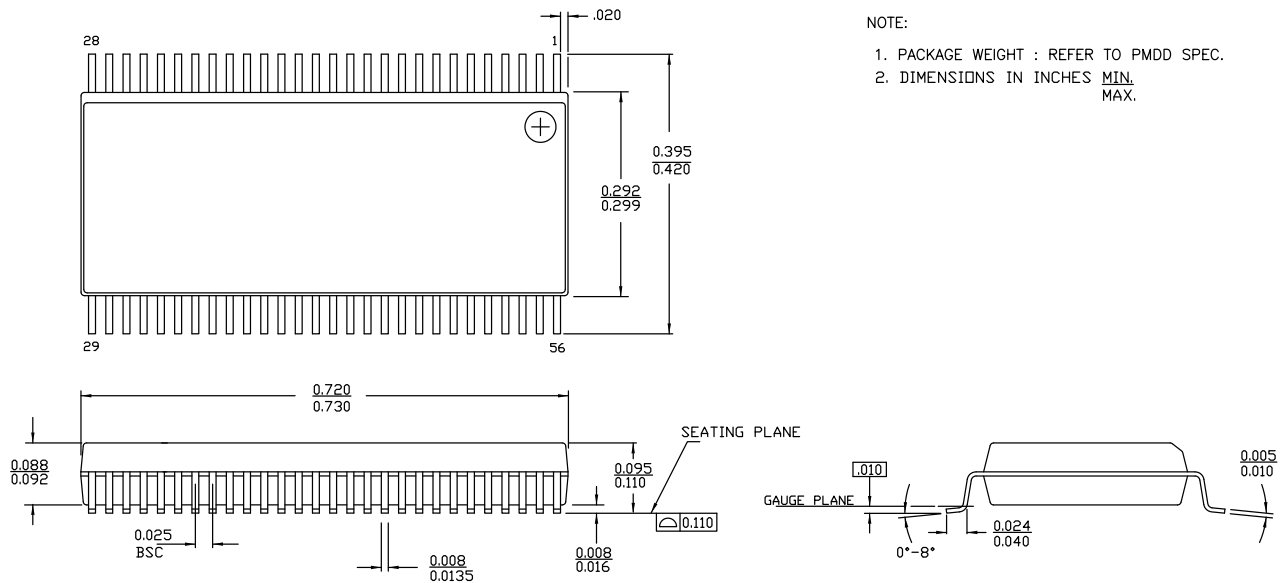


NOTES:

1. [HATCHED AREA] HATCH AREA IS SOLDERABLE EXPOSED METAL.
2. REFERENCE JEDEC#: MO-220
3. PACKAGE WEIGHT: 13 ± 1 mg
4. ALL DIMENSIONS ARE IN MILLIMETERS

001-13191 *G

Figure 28. 56-pin (300-Mil) SSOP



NOTE:

1. PACKAGE WEIGHT : REFER TO PMDD SPEC.
2. DIMENSIONS IN INCHES MIN.
MAX.

51-85062 *F

Important Note For information on the preferred dimensions for mounting QFN packages, see the following application note, *Application Notes for Surface Mount Assembly of Amkor's MicroLeadFrame (MLF) Packages* available at <http://www.amkor.com>.

Thermal Impedances

Table 40. Thermal Impedances per Package

| Package | Typical θ_{JA} ^[28] |
|----------------------------|---------------------------------------|
| 8-pin PDIP | 120 °C/W |
| 20-pin SSOP | 116 °C/W |
| 20-pin SOIC | 79 °C/W |
| 28-pin PDIP | 67 °C/W |
| 28-pin SSOP | 95 °C/W |
| 28-pin SOIC | 68 °C/W |
| 44-pin TQFP | 61 °C/W |
| 48-pin SSOP | 69 °C/W |
| 48-pin QFN ^[29] | 18 °C/W |
| 56-pin SSOP | 47 °C/W |

Capacitance on Crystal Pins

Table 41. Typical Package Capacitance on Crystal Pins

| Package | Package Capacitance |
|-------------|---------------------|
| 8-pin PDIP | 2.8 pF |
| 20-pin SSOP | 2.6 pF |
| 20-pin SOIC | 2.5 pF |
| 28-pin PDIP | 3.5 pF |
| 28-pin SSOP | 2.8 pF |
| 28-pin SOIC | 2.7 pF |
| 44-pin TQFP | 2.6 pF |
| 48-pin SSOP | 3.3 pF |
| 48-pin QFN | 2.3 pF |
| 56-pin SSOP | 3.3 pF |

Solder Reflow Specifications

The following table shows the solder reflow temperature limits that must not be exceeded. Thermap ramp rate should 3 °C or lower.

Table 42. Solder Reflow Specifications

| Package | Maximum Peak Temperature (T_C) ^[30] | Maximum Time above $T_C - 5$ °C |
|-------------|--|---------------------------------|
| 8-pin PDIP | 260 °C | 30 seconds |
| 20-pin SSOP | 260 °C | 30 seconds |
| 20-pin SOIC | 260 °C | 30 seconds |
| 28-pin PDIP | 260 °C | 30 seconds |
| 28-pin SSOP | 260 °C | 30 seconds |
| 28-pin SOIC | 260 °C | 30 seconds |
| 44-pin TQFP | 260 °C | 30 seconds |
| 48-pin SSOP | 260 °C | 30 seconds |
| 48-pin QFN | 260 °C | 30 seconds |
| 56-pin SSOP | 260 °C | 30 seconds |

Notes

28. $T_J = T_A + \text{POWER} \times \theta_{JA}$.

29. To achieve the thermal impedance specified for the QFN package, refer to "Application Notes for Surface Mount Assembly of Amkor's Micro-LeadFrame (MLF) Packages" available at <http://www.amkor.com>.

30. Refer to Table 44 on page 53.

Development Tool Selection

This chapter presents the development tools available for all current PSoC device families including the CY8C27x43 family.

Software

PSoC Designer™

At the core of the PSoC development software suite is PSoC Designer, used to generate PSoC firmware applications. PSoC Designer is available free of charge at <http://www.cypress.com> and includes a free C compiler.

PSoC Programmer

Flexible enough to be used on the bench in development, yet suitable for factory programming, PSoC Programmer works either as a standalone programming application or it can operate directly from PSoC Designer or PSoC Express. PSoC Programmer software is compatible with both PSoC ICE-Cube In-Circuit Emulator and PSoC MiniProg. PSoC programmer is available free of charge at <http://www.cypress.com>.

Development Kits

All development kits can be purchased from the Cypress Online Store.

CY3215-DK Basic Development Kit

The **CY3215-DK** is for prototyping and development with PSoC Designer. This kit supports in-circuit emulation and the software interface lets you to run, halt, and single step the processor and view the content of specific memory locations. Advance emulation features also supported through PSoC Designer. The kit includes:

- PSoC Designer Software CD
- ICE-Cube In-Circuit Emulator
- ICE Flex-Pod for CY8C29x66 Family
- Cat-5 Adapter
- Mini-Eval Programming Board
- 110 ~ 240 V Power Supply, Euro-Plug Adapter
- iMAGEcraft C Compiler
- ISSP Cable
- USB 2.0 Cable and Blue Cat-5 Cable
- 2 CY8C29466-24PXI 28-PDIP Chip Samples

Evaluation Tools

All evaluation tools can be purchased from the Cypress Online Store.

CY3210-MiniProg1

The **CY3210-MiniProg1** kit lets you to program PSoC devices via the MiniProg1 programming unit. The MiniProg is a small, compact prototyping programmer that connects to the PC via a provided USB 2.0 cable. The kit includes:

- MiniProg Programming Unit
- MiniEval Socket Programming and Evaluation Board
- 28-pin CY8C29466-24PXI PDIP PSoC Device Sample
- 28-pin CY8C27443-24PXI PDIP PSoC Device Sample
- PSoC Designer Software CD
- Getting Started Guide
- USB 2.0 Cable

CY3210-PSoCEval1

The **CY3210-PSoCEval1** kit features an evaluation board and the MiniProg1 programming unit. The evaluation board includes an LCD module, potentiometer, LEDs, and plenty of bread-boarding space to meet all of your evaluation needs. The kit includes:

- Evaluation Board with LCD Module
- MiniProg Programming Unit
- 28-pin CY8C29466-24PXI PDIP PSoC Device Sample (2)
- PSoC Designer Software CD
- Getting Started Guide
- USB 2.0 Cable

CY3214-PSoCEvalUSB

The **CY3214-PSoCEvalUSB** evaluation kit features a development board for the CY8C24794-24LFXI PSoC device. Special features of the board include both USB and capacitive sensing development and debugging support. This evaluation board also includes an LCD module, potentiometer, LEDs, an enunciator and plenty of bread boarding space to meet all of your evaluation needs. The kit includes:

- PSoCEvalUSB Board
- LCD Module
- MiniProg Programming Unit
- Mini USB Cable
- PSoC Designer and Example Projects CD
- Getting Started Guide
- Wire Pack

Device Programmers

All device programmers can be purchased from the Cypress Online Store.

CY3216 Modular Programmer

The **CY3216 Modular Programmer kit** features a modular programmer and the MiniProg1 programming unit. The modular programmer includes three programming module cards and supports multiple Cypress products. The kit includes:

- Modular Programmer Base
- 3 Programming Module Cards
- MiniProg Programming Unit
- PSoC Designer Software CD
- Getting Started Guide
- USB 2.0 Cable

CY3207ISSP In-System Serial Programmer (ISSP)

The **CY3207ISSP** is a production programmer. It includes protection circuitry and an industrial case that is more robust than the MiniProg in a production-programming environment.

Note CY3207ISSP needs special software and is not compatible with PSoC Programmer. The kit includes:

- CY3207 Programmer Unit
- PSoC ISSP Software CD
- 110 ~ 240 V Power Supply, Euro-Plug Adapter
- USB 2.0 Cable

Accessories (Emulation and Programming)

Table 43. Emulation and Programming Accessories

| Part # | Pin Package | Flex-Pod Kit ^[31] | Foot Kit ^[32] | Adapter ^[33] |
|------------------|-------------|------------------------------|--------------------------|--|
| CY8C27143-24PXI | 8-pin PDIP | CY3250-27XXX | CY3250-8PDIP-FK | Adapters can be found at http://www.emulation.com . |
| CY8C27243-24PVXI | 20-pin SSOP | CY3250-27XXX | CY3250-20SSOP-FK | |
| CY8C27243-24SXI | 20-pin SOIC | CY3250-27XXX | CY3250-20SOIC-FK | |
| CY8C27443-24PXI | 28-pin PDIP | CY3250-27XXX | CY3250-28PDIP-FK | |
| CY8C27443-24PVXI | 28-pin SSOP | CY3250-27XXX | CY3250-28SSOP-FK | |
| CY8C27443-24SXI | 28-pin SOIC | CY3250-27XXX | CY3250-28SOIC-FK | |
| CY8C27543-24AXI | 44-pin TQFP | CY3250-27XXX | CY3250-44TQFP-FK | |
| CY8C27643-24PVXI | 48-pin SSOP | CY3250-27XXX | CY3250-48SSOP-FK | |
| CY8C27643-24LTXI | 48-pin QFN | CY3250-27XXXQFN | CY3250-48QFN-FK | |

Notes

31. Flex-Pod kit includes a practice flex-pod and a practice PCB, in addition to two flex-pods.

32. Foot kit includes surface mount feet that can be soldered to the target PCB.

33. Programming adapter converts non-DIP package to DIP footprint. Specific details and ordering information for each of the adapters can be found at <http://www.emulation.com>.

Ordering Information

The following table lists the CY8C27x43 PSoC device's key package features and ordering codes.

Table 44. CY8C27x43 PSoC Device Key Features and Ordering Information

| Package | Ordering Code | Flash (Bytes) | RAM (Bytes) | Switch Mode Pump | Temperature Range | Digital Blocks (Rows of 4) | Analog Blocks (Columns of 3) | Digital I/O Pins | Analog Inputs | Analog Outputs | XRES Pin |
|---------------------------------------|----------------------------------|---------------|-------------|------------------|-------------------|----------------------------|------------------------------|------------------|---------------|----------------|----------|
| 8-pin (300-Mil) DIP | CY8C27143-24PXI | 16 K | 256 | No | –40 °C to +85 °C | 8 | 12 | 6 | 4 | 4 | No |
| 20-pin (210-Mil) SSOP | CY8C27243-24PVXI | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 16 | 8 | 4 | Yes |
| 20-pin (210-Mil) SSOP (Tape and Reel) | CY8C27243-24PVXIT | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 16 | 8 | 4 | Yes |
| 20-pin (300-Mil) SOIC | CY8C27243-24SXI | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 16 | 8 | 4 | Yes |
| 20-pin (300-Mil) SOIC (Tape and Reel) | CY8C27243-24SXIT | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 16 | 8 | 4 | Yes |
| 28-pin (300-Mil) DIP | CY8C27443-24PXI | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 24 | 12 | 4 | Yes |
| 28-pin (210-Mil) SSOP | CY8C27443-24PVXI | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 24 | 12 | 4 | Yes |
| 28-pin (210-Mil) SSOP (Tape and Reel) | CY8C27443-24PVXIT | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 24 | 12 | 4 | Yes |
| 28-pin (300-Mil) SOIC | CY8C27443-24SXI | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 24 | 12 | 4 | Yes |
| 28-pin (300-Mil) SOIC (Tape and Reel) | CY8C27443-24SXIT | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 24 | 12 | 4 | Yes |
| 44-pin TQFP | CY8C27543-24AXI | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 40 | 12 | 4 | Yes |
| 44-pin TQFP (Tape and Reel) | CY8C27543-24AXIT | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 40 | 12 | 4 | Yes |
| 48-pin (300-Mil) SSOP | CY8C27643-24PVXI | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 44 | 12 | 4 | Yes |
| 48-pin (300-Mil) SSOP (Tape and Reel) | CY8C27643-24PVXIT | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 44 | 12 | 4 | Yes |
| 48-pin (7 × 7 × 1 mm) QFN (Sawn) | CY8C27643-24LTXI | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 44 | 12 | 4 | Yes |
| 48-pin (7 × 7 × 1 mm) QFN (Sawn) | CY8C27643-24LTXIT | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 44 | 12 | 4 | Yes |
| 56-pin OCD SSOP | CY8C27002-24PVXI ^[34] | 16 K | 256 | Yes | –40 °C to +85 °C | 8 | 12 | 44 | 14 | 4 | Yes |

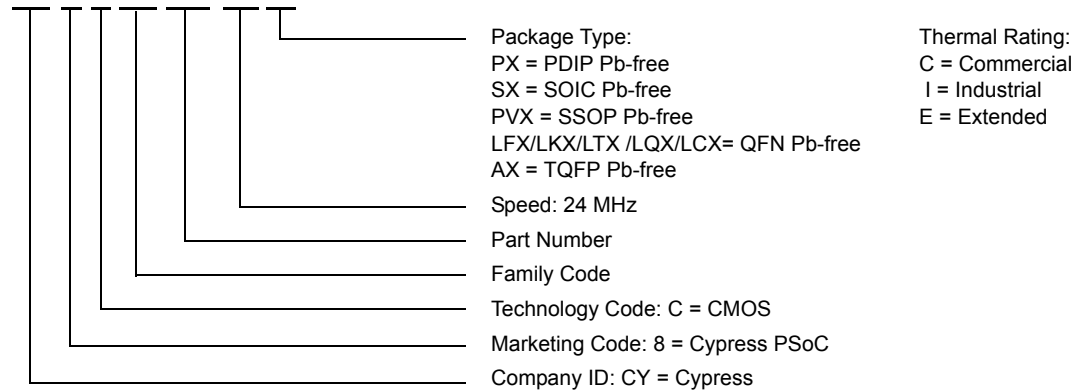
Note For Die sales information, contact a local Cypress sales office or Field Applications Engineer (FAE).

Note

³⁴. This part may be used for in-circuit debugging. It is NOT available for production.

Ordering Code Definitions

CY 8 C 27 xxx-24xx



Acronyms

Table 45 lists the acronyms that are used in this document.

Table 45. Acronyms Used in this Datasheet

| Acronym | Description | Acronym | Description |
|---------|---|---------|---|
| AC | alternating current | MIPS | million instructions per second |
| ADC | analog-to-digital converter | OCD | on-chip debug |
| API | application programming interface | PCB | printed circuit board |
| CMOS | complementary metal oxide semiconductor | PDIP | plastic dual-in-line package |
| CPU | central processing unit | PGA | programmable gain amplifier |
| CRC | cyclic redundancy check | PLL | phase-locked loop |
| CT | continuous time | POR | power on reset |
| DAC | digital-to-analog converter | PPOR | precision power on reset |
| DC | direct current | PRS | pseudo-random sequence |
| DTMF | dual-tone multi-frequency | PSoC | Programmable System-on-Chip |
| ECO | external crystal oscillator | PWM | pulse width modulator |
| EEPROM | electrically erasable programmable read-only memory | QFN | quad flat no leads |
| GPIO | general purpose I/O | RTC | real time clock |
| ICE | in-circuit emulator | SAR | successive approximation |
| IDE | integrated development environment | SC | switched capacitor |
| ILO | internal low speed oscillator | SMP | switch mode pump |
| IMO | internal main oscillator | SOIC | small-outline integrated circuit |
| I/O | input/output | SPI | serial peripheral interface |
| IrDA | infrared data association | SRAM | static random access memory |
| ISSP | in-system serial programming | SROM | supervisory read only memory |
| LCD | liquid crystal display | SSOP | shrink small-outline package |
| LED | light-emitting diode | TQFP | thin quad flat pack |
| LPC | low power comparator | UART | universal asynchronous receiver / transmitter |
| LVD | low voltage detect | USB | universal serial bus |
| MAC | multiply-accumulate | WDT | watchdog timer |
| MCU | microcontroller unit | XRES | external reset |

Reference Documents

CY8CPLC20, CY8CLED16P01, CY8C29X66, CY8C27X43, CY8C24X94, CY8C24X23, CY8C24X23A, CY8C22X13, CY8C21X34, CY8C21X34B, CY8C21X23, CY7C64215, CY7C603XX, CY8CNP1XX, and CYWUSB6953 PSoC(R) Programmable System-on-chip Technical Reference Manual (TRM) (001-14463)

PSoC® 1– Reading and Writing Flash - AN2015 (001-40459)

Adjusting PSoC® Trims for 3.3 V and 2.7 V Operation – AN2012 (001-17397)

Understanding Data Sheet Jitter Specifications for Cypress Timing Products – AN5054 (001-14503)

Application Notes for Surface Mount Assembly of Amkor's MicroLeadFrame (MLF) Packages – available at <http://www.amkor.com>.

Document Conventions

Units of Measure

Table 46 lists the unit sof measures.

Table 46. Units of Measure

| Symbol | Unit of Measure | Symbol | Unit of Measure |
|--------|-----------------|--------|-------------------------|
| dB | decibels | ms | millisecond |
| °C | degree Celsius | ns | nanosecond |
| fF | femto farad | ps | picosecond |
| pF | picofarad | μV | microvolts |
| kHz | kilohertz | mV | millivolts |
| MHz | megahertz | mVpp | millivolts peak-to-peak |
| rt-Hz | root hertz | nV | nanovolts |
| kΩ | kilohm | V | volts |
| Ω | ohm | μW | microwatts |
| μA | microampere | W | watt |
| mA | milliampere | mm | millimeter |
| nA | nanoampere | ppm | parts per million |
| pA | pikoampere | % | percent |
| μs | microsecond | | |

Numeric Conventions

Hexadecimal numbers are represented with all letters in uppercase with an appended lowercase 'h' (for example, '14h' or '3Ah'). Hexadecimal numbers may also be represented by a '0x' prefix, the C coding convention. Binary numbers have an appended lowercase 'b' (for example, '01010100b' or '01000011b'). Numbers not indicated by an 'h', 'b', or 0x are decimal.

Glossary

| | |
|---|---|
| active high | <ol style="list-style-type: none"> 1. A logic signal having its asserted state as the logic 1 state. 2. A logic signal having the logic 1 state as the higher voltage of the two states. |
| analog blocks | The basic programmable opamp circuits. These are SC (switched capacitor) and CT (continuous time) blocks. These blocks can be interconnected to provide ADCs, DACs, multi-pole filters, gain stages, and much more. |
| analog-to-digital (ADC) | A device that changes an analog signal to a digital signal of corresponding magnitude. Typically, an ADC converts a voltage to a digital number. The digital-to-analog (DAC) converter performs the reverse operation. |
| Application programming interface (API) | A series of software routines that comprise an interface between a computer application and lower level services and functions (for example, user modules and libraries). APIs serve as building blocks for programmers that create software applications. |
| asynchronous | A signal whose data is acknowledged or acted upon immediately, irrespective of any clock signal. |
| Bandgap reference | A stable voltage reference design that matches the positive temperature coefficient of VT with the negative temperature coefficient of VBE, to produce a zero temperature coefficient (ideally) reference. |
| bandwidth | <ol style="list-style-type: none"> 1. The frequency range of a message or information processing system measured in hertz. 2. The width of the spectral region over which an amplifier (or absorber) has substantial gain (or loss); it is sometimes represented more specifically as, for example, full width at half maximum. |

Glossary (continued)

| | |
|-------------------------------|--|
| bias | <ol style="list-style-type: none"> 1. A systematic deviation of a value from a reference value. 2. The amount by which the average of a set of values departs from a reference value. 3. The electrical, mechanical, magnetic, or other force (field) applied to a device to establish a reference level to operate the device. |
| block | <ol style="list-style-type: none"> 1. A functional unit that performs a single function, such as an oscillator. 2. A functional unit that may be configured to perform one of several functions, such as a digital PSoC block or an analog PSoC block. |
| buffer | <ol style="list-style-type: none"> 1. A storage area for data that is used to compensate for a speed difference, when transferring data from one device to another. Usually refers to an area reserved for IO operations, into which data is read, or from which data is written. 2. A portion of memory set aside to store data, often before it is sent to an external device or as it is received from an external device. 3. An amplifier used to lower the output impedance of a system. |
| bus | <ol style="list-style-type: none"> 1. A named connection of nets. Bundling nets together in a bus makes it easier to route nets with similar routing patterns. 2. A set of signals performing a common function and carrying similar data. Typically represented using vector notation; for example, address[7:0]. 3. One or more conductors that serve as a common connection for a group of related devices. |
| clock | The device that generates a periodic signal with a fixed frequency and duty cycle. A clock is sometimes used to synchronize different logic blocks. |
| comparator | An electronic circuit that produces an output voltage or current whenever two input levels simultaneously satisfy predetermined amplitude requirements. |
| compiler | A program that translates a high level language, such as C, into machine language. |
| configuration space | In PSoC devices, the register space accessed when the XIO bit, in the CPU_F register, is set to '1'. |
| crystal oscillator | An oscillator in which the frequency is controlled by a piezoelectric crystal. Typically a piezoelectric crystal is less sensitive to ambient temperature than other circuit components. |
| cyclic redundancy check (CRC) | A calculation used to detect errors in data communications, typically performed using a linear feedback shift register. Similar calculations may be used for a variety of other purposes such as data compression. |
| data bus | A bi-directional set of signals used by a computer to convey information from a memory location to the central processing unit and vice versa. More generally, a set of signals used to convey data between digital functions. |
| debugger | A hardware and software system that allows you to analyze the operation of the system under development. A debugger usually allows the developer to step through the firmware one step at a time, set break points, and analyze memory. |
| dead band | A period of time when neither of two or more signals are in their active state or in transition. |
| digital blocks | The 8-bit logic blocks that can act as a counter, timer, serial receiver, serial transmitter, CRC generator, pseudo-random number generator, or SPI. |
| digital-to-analog (DAC) | A device that changes a digital signal to an analog signal of corresponding magnitude. The analog-to-digital (ADC) converter performs the reverse operation. |

Glossary (continued)

| | |
|---------------------------------|--|
| duty cycle | The relationship of a clock period high time to its low time, expressed as a percent. |
| emulator | Duplicates (provides an emulation of) the functions of one system with a different system, so that the second system appears to behave like the first system. |
| External Reset (XRES) | An active high signal that is driven into the PSoC device. It causes all operation of the CPU and blocks to stop and return to a pre-defined state. |
| Flash | An electrically programmable and erasable, non-volatile technology that provides you the programmability and data storage of EPROMs, plus in-system erasability. Non-volatile means that the data is retained when power is OFF. |
| Flash block | The smallest amount of Flash ROM space that may be programmed at one time and the smallest amount of Flash space that may be protected. A Flash block holds 64 bytes. |
| frequency | The number of cycles or events per unit of time, for a periodic function. |
| gain | The ratio of output current, voltage, or power to input current, voltage, or power, respectively. Gain is usually expressed in dB. |
| I ² C | A two-wire serial computer bus by Philips Semiconductors (now NXP Semiconductors). I2C is an Inter-Integrated Circuit. It is used to connect low-speed peripherals in an embedded system. The original system was created in the early 1980s as a battery control interface, but it was later used as a simple internal bus system for building control electronics. I2C uses only two bi-directional pins, clock and data, both running at +5V and pulled high with resistors. The bus operates at 100 kbits/second in standard mode and 400 kbits/second in fast mode. |
| ICE | The in-circuit emulator that allows you to test the project in a hardware environment, while viewing the debugging device activity in a software environment (PSoC Designer). |
| input/output (I/O) | A device that introduces data into or extracts data from a system. |
| interrupt | A suspension of a process, such as the execution of a computer program, caused by an event external to that process, and performed in such a way that the process can be resumed. |
| interrupt service routine (ISR) | A block of code that normal code execution is diverted to when the M8C receives a hardware interrupt. Many interrupt sources may each exist with its own priority and individual ISR code block. Each ISR code block ends with the RETI instruction, returning the device to the point in the program where it left normal program execution. |
| jitter | <ol style="list-style-type: none"> 1. A misplacement of the timing of a transition from its ideal position. A typical form of corruption that occurs on serial data streams. 2. The abrupt and unwanted variations of one or more signal characteristics, such as the interval between successive pulses, the amplitude of successive cycles, or the frequency or phase of successive cycles. |
| low-voltage detect (LVD) | A circuit that senses V_{DD} and provides an interrupt to the system when V_{DD} falls lower than a selected threshold. |
| M8C | An 8-bit Harvard-architecture microprocessor. The microprocessor coordinates all activity inside a PSoC by interfacing to the Flash, SRAM, and register space. |
| master device | A device that controls the timing for data exchanges between two devices. Or when devices are cascaded in width, the master device is the one that controls the timing for data exchanges between the cascaded devices and an external interface. The controlled device is called the slave device . |

Glossary (continued)

| | |
|-----------------------------|---|
| microcontroller | An integrated circuit chip that is designed primarily for control systems and products. In addition to a CPU, a microcontroller typically includes memory, timing circuits, and IO circuitry. The reason for this is to permit the realization of a controller with a minimal quantity of chips, thus achieving maximal possible miniaturization. This in turn, reduces the volume and the cost of the controller. The microcontroller is normally not used for general-purpose computation as is a microprocessor. |
| mixed-signal | The reference to a circuit containing both analog and digital techniques and components. |
| modulator | A device that imposes a signal on a carrier. |
| noise | <ol style="list-style-type: none"> 1. A disturbance that affects a signal and that may distort the information carried by the signal. 2. The random variations of one or more characteristics of any entity such as voltage, current, or data. |
| oscillator | A circuit that may be crystal controlled and is used to generate a clock frequency. |
| parity | A technique for testing transmitting data. Typically, a binary digit is added to the data to make the sum of all the digits of the binary data either always even (even parity) or always odd (odd parity). |
| Phase-locked loop (PLL) | An electronic circuit that controls an oscillator so that it maintains a constant phase angle relative to a reference signal. |
| pinouts | The pin number assignment: the relation between the logical inputs and outputs of the PSoC device and their physical counterparts in the printed circuit board (PCB) package. Pinouts involve pin numbers as a link between schematic and PCB design (both being computer generated files) and may also involve pin names. |
| port | A group of pins, usually eight. |
| Power on reset (POR) | A circuit that forces the PSoC device to reset when the voltage is lower than a pre-set level. This is a type of hardware reset. |
| PSoC® | Cypress Semiconductor's PSoC® is a registered trademark and Programmable System-on-Chip™ is a trademark of Cypress. |
| PSoC Designer™ | The software for Cypress' Programmable System-on-Chip technology. |
| pulse width modulator (PWM) | An output in the form of duty cycle which varies as a function of the applied measurand |
| RAM | An acronym for random access memory. A data-storage device from which data can be read out and new data can be written in. |
| register | A storage device with a specific capacity, such as a bit or byte. |
| reset | A means of bringing a system back to a know state. See hardware reset and software reset. |
| ROM | An acronym for read only memory. A data-storage device from which data can be read out, but new data cannot be written in. |
| serial | <ol style="list-style-type: none"> 1. Pertaining to a process in which all events occur one after the other. 2. Pertaining to the sequential or consecutive occurrence of two or more related activities in a single device or channel. |
| settling time | The time it takes for an output signal or value to stabilize after the input has changed from one value to another. |

Glossary (continued)

| | |
|-----------------|---|
| shift register | A memory storage device that sequentially shifts a word either left or right to output a stream of serial data. |
| slave device | A device that allows another device to control the timing for data exchanges between two devices. Or when devices are cascaded in width, the slave device is the one that allows another device to control the timing of data exchanges between the cascaded devices and an external interface. The controlling device is called the master device. |
| SRAM | An acronym for static random access memory. A memory device where you can store and retrieve data at a high rate of speed. The term static is used because, after a value is loaded into an SRAM cell, it remains unchanged until it is explicitly altered or until power is removed from the device. |
| SROM | An acronym for supervisory read only memory. The SROM holds code that is used to boot the device, calibrate circuitry, and perform Flash operations. The functions of the SROM may be accessed in normal user code, operating from Flash. |
| stop bit | A signal following a character or block that prepares the receiving device to receive the next character or block. |
| synchronous | <ol style="list-style-type: none"> 1. A signal whose data is not acknowledged or acted upon until the next active edge of a clock signal. 2. A system whose operation is synchronized by a clock signal. |
| tri-state | A function whose output can adopt three states: 0, 1, and Z (high-impedance). The function does not drive any value in the Z state and, in many respects, may be considered to be disconnected from the rest of the circuit, allowing another output to drive the same net. |
| UART | A UART or universal asynchronous receiver-transmitter translates between parallel bits of data and serial bits. |
| user modules | Pre-build, pre-tested hardware/firmware peripheral functions that take care of managing and configuring the lower level Analog and Digital PSoC Blocks. User Modules also provide high level API (Application Programming Interface) for the peripheral function. |
| user space | The bank 0 space of the register map. The registers in this bank are more likely to be modified during normal program execution and not just during initialization. Registers in bank 1 are most likely to be modified only during the initialization phase of the program. |
| V _{DD} | A name for a power net meaning "voltage drain." The most positive power supply signal. Usually 5 V or 3.3 V. |
| V _{SS} | A name for a power net meaning "voltage source." The most negative power supply signal. |
| watchdog timer | A timer that must be serviced periodically. If it is not serviced, the CPU resets after a specified period of time. |

Appendix: Silicon Errata for the PSoC[®] Programmable System on Chip™, CY8C27143, CY8C27243, CY8C27443, CY8C27543, and CY8C27643 Product Family

This section describes the errata for the PSoC[®] Programmable System on Chip™, CY8C27143, CY8C27243, CY8C27443, CY8C27543, and CY8C27643. Details include errata trigger conditions, scope of impact, available workarounds, and silicon revision applicability.

Contact your local Cypress Sales Representative if you have questions.

Part Numbers Affected

| Part Number |
|-------------|
| CY8C27143 |
| CY8C27243 |
| CY8C27443 |
| CY8C27543 |
| CY8C27643 |

PSoC[®] Programmable System on Chip™ Qualification Status

CY8C27XXX Rev. B – In Production

PSoC[®] Programmable System on Chip™ Errata Summary

The following table defines the errata applicability to available PSoC[®] Programmable System on Chip™ family devices. An "X" indicates that the erratum pertains to the selected device.

Note: Errata items, in the table below, are hyperlinked. Click on any item entry to jump to its description.

| Items | Part Number | Silicon Revision | Fix Status |
|--|--------------------|------------------|---|
| [1] Reading from chained SPI slaves does not give correct results. | All parts affected | B | No silicon fix planned. Workaround is required. |

1. Reading from chained SPI slaves does not give correct results

■ Problem Definition

When multiple Digital Communication Blocks are configured as SPI Slave devices and one SPI's output (MISO) is connected to the input (MOSI) of the second SPI, the serial data will be correctly forwarded, but reading the results from the DCBxxDR2 register in the second device will result in the last bit shifted in being incorrect.

■ Parameters Affected

NA

■ Trigger Condition(S)

Connection of the output of one PSoC SPI slave to the input of another PSoC SPI slave.

■ Scope of Impact

PSoC end user designs incorporating SPI configurations with multiple Digital Communication Blocks configured as SPI Slave devices with one SPI output (MISO) connected to the input (MOSI) of the second SPI.

■ Workaround

This solution requires the use of an additional digital block configured as a PWM8 set for a 50% duty cycle. The same clock is routed to the PWM8, as goes to the two SPI slaves. The PWM8 User Module is parameterized to have a Period of 15 (so that it divides by 16) and a pulse width of 8 (with CompType set to "Less Than Or Equal" (so that it has a "1" pulse width of 8 clocks and a "0" pulse width of 8 clocks). The output of the PWM8 is connected to the Slave Select (/SS) of each SPI slave. One of these connections is direct. The other connection is inverted using the row output LUT. This configuration will "ping pong" the two SPIs so that each one receives alternating bytes. This solution works especially well in cases where the two SPI slaves are being used to implement a 16-bit shift register, the following method has worked.

■ Fix Status

There are no fixes planned. The workaround listed above should be used.

Document History Page

| Document Title: CY8C27143, CY8C27243, CY8C27443, CY8C27543, CY8C27643, PSoC® Programmable System-on-Chip™ Document Number: 38-12012 | | | | |
|--|---------|---------------------|-----------------|---|
| Revision | ECN | Origin of Change | Submission Date | Description of Change |
| ** | 127087 | New Silicon. | 7/01/2003 | New document (Revision **). |
| *A | 128780 | Engineering and NWJ | 7/29/2003 | New electrical spec additions, fix of Core Architecture links, corrections to some text, tables, drawings, and format. |
| *B | 128992 | NWJ | 8/14/2003 | Interrupt controller table fixed, refinements to Electrical Spec section and Register chapter. |
| *C | 129283 | NWJ | 8/28/2003 | Significant changes to the Electrical Specifications section. |
| *D | 129442 | NWJ | 9/09/2003 | Changes made to Electrical Spec section. Added 20/28-Lead SOIC packages and pinouts. |
| *E | 130129 | NWJ | 10/13/2003 | Revised document for Silicon Revision A. |
| *F | 130651 | NWJ | 10/28/2003 | Refinements to Electrical Specification section and I2C chapter. |
| *G | 131298 | NWJ | 11/18/2003 | Revisions to GDI, RDI, and Digital Block chapters. Revisions to AC Digital Block Spec and miscellaneous register changes. |
| *H | 229416 | SFV | See ECN | New datasheet format and organization. Reference the <i>PSoC Programmable System-on-Chip Technical Reference Manual</i> for additional information. Title change. |
| *I | 247529 | SFV | See ECN | Added Silicon B information to this datasheet. |
| *J | 355555 | HMT | See ECN | Add DS standards, update device table, swap 48-pin SSOP 45 and 46, add Reflow Peak Temp. table. Add new color and logo. Re-add pinout ISSP notation. Add URL to preferred dimensions for mounting MLF packages. Update Transmitter and Receiver AC Digital Block Electrical Specifications. |
| *K | 523233 | HMT | See ECN | Add Low Power Comparator (LPC) AC/DC electrical spec. tables. Add new Dev. Tool section. Add CY8C20x34 to PSoC Device Characteristics table. Add OCD pinout and package diagram. Add ISSP note to pinout tables. Update package diagram revisions. Update typical and recommended Storage Temperature per industrial specs. Update CY branding and QFN convention. Update copyright and trademarks. |
| *L | 2545030 | YARA | 07/29/2008 | Added note to DC Analog Reference Specification table and Ordering Information. |
| *M | 2696188 | DPT / PYRS | 04/22/2009 | Changed title from "CY8C27143, CY8C27243, CY8C27443, CY8C27543, and CY8C27643 PSoC Mixed Signal Array Final datasheet" to "CY8C27143, CY8C27243, CY8C27443, CY8C27543, CY8C27643 PSoC® Programmable System-on-Chip™". Updated datasheet template. Added 48-Pin QFN (Sawn) package outline diagram and Ordering information details for CY8C27643-24LTXI and CY8C27643-24LTXIT parts |
| *N | 2762501 | MAXK | 09/11/2009 | Updated DC GPIO, AC Chip-Level, and AC Programming Specifications as follows: Modified T _{WRITE} specification. Replaced T _{RAMP} (time) specification with SR _{POWER_UP} (slew rate) specification. Added note [9] to Flash Endurance specification. Added I _{OH} , I _{OL} , DCILO, F32K_U, T _{POWERUP} , T _{ERASEALL} , T _{PROGRAM_HOT} , and T _{PROGRAM_COLD} specifications. |
| *O | 2811860 | ECU | 11/20/2009 | Added Contents page. In the Ordering Information table, added 48 Sawn QFN (LTXI) to the Silicon B parts. Updated 28-Pin package drawing (51-85014) |

Document History Page (continued)

Document Title: CY8C27143, CY8C27243, CY8C27443, CY8C27543, CY8C27643, PSoC® Programmable System-on-Chip™
Document Number: 38-12012

| Revision | ECN | Origin of Change | Submission Date | Description of Change |
|----------|---------|------------------|-----------------|---|
| *P | 2899847 | NJF / HMI | 03/26/10 | Added CY8C27643-24LKXI and CY8C27643-24LTXI to Emulation and Programming Accessories on page 52 . Updated Cypress website links. Added T _{BAKETEMP} and T _{BAKETIME} parameters in Absolute Maximum Ratings on page 19 . Updated AC electrical specs. Updated Note in Packaging Information on page 44 . Updated package diagrams. Updated Thermal Impedances , Solder Reflow Specifications , and Capacitance on Crystal Pins . Removed Third Party Tools and Build a PSoC Emulator into your Board. Updated Ordering Code Definitions on page 54 . Updated Ordering Information table. Updated links in Sales, Solutions, and Legal Information . |
| *Q | 2949177 | ECU | 06/10/2010 | Updated content to match current style guide and datasheet template. No technical updates |
| *R | 3032514 | NJF | 09/17/10 | Added PSoC Device Characteristics table . Added DC I ² C Specifications table. Added F _{32K_U} max limit. Added T _{jitter} IMO specification, removed existing jitter specifications. Updated Analog reference tables. Updated Units of Measure, Acronyms, Glossary, and References sections. Updated solder reflow specifications. No specific changes were made to AC Digital Block Specifications table and I ² C Timing Diagram. They were updated for clearer understanding. Updated Figure 13 since the labelling for y-axis was incorrect. Template and styles update. |
| *S | 3092470 | GDK | 11/22/10 | Removed the following pruned parts from the datasheet. CY8C27643-24LFXIT CY8C27643-24LFXI |
| *T | 3180303 | HMI | 02/23/2011 | Updated Packaging Information . |
| *U | 3378917 | GIR | 09/28/2011 | The text "Pin must be left floating" is included under Description of NC pin in Table 8 on page 14 . Updated Table 42 on page 50 for improved clarity. Removed Footnote # 31 and its reference under Table 42 on page 50 . Removed inactive part CY8C27643-24LKXI from Table 43 on page 52 . |
| *V | 3525102 | UVS | 02/14/2012 | Updated 48-pin sawn QFN package revision. No technical update. |
| *W | 3598316 | LURE / XZNG | 04/24/2012 | Changed the PWM description string from "8- to 32-bit" to "8- and 16-bit". |
| *X | 3959251 | GVH | 04/09/2013 | Updated Packaging Information : spec 51-85014 – Changed revision from *F to *G. spec 51-85061 – Changed revision from *E to *F. spec 001-13191 – Changed revision from *F to *G. spec 51-85062 – Changed revision from *E to *F. Added Appendix: Silicon Errata for the PSoC® Programmable System on Chip™, CY8C27143, CY8C27243, CY8C27443, CY8C27543, and CY8C27643 Product Family . |

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